



HAC RF TEST REPORT

No. 2011HAC00012-1

For

Huawei Technologies Co.,Ltd.

CDMA 1X Digital Mobile Phone with Bluetooth

M615

With

Hardware Version: Ver.B

Software Version: M615C1TB106

FCCID: QISC6070

Results Summary: M Category = M4

Issued Date: 2011-05-08



No. DGA-PL-114/01-02

Note:

The test results in this test report relate only to the devices specified in this report. This report shall not be reproduced except in full without the written approval of TMC Beijing.

Test Laboratory:

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1 Test Laboratory

1.1 Testing Location

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Telephone: +86-10-62304633
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1.2 Testing Environment

Temperature: 18°C~25 °C,
Relative humidity: 30%~ 70%
Ground system resistance: < 0.5 Ω

Ambient noise is checked and found very low and in compliance with requirement of standards.
Reflection of surrounding objects is minimized and in compliance with requirement of standards.

1.3 Project Data

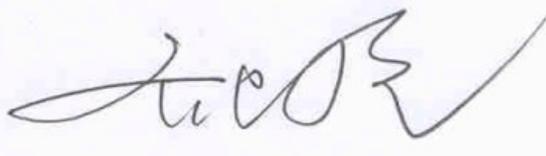
Project Leader: Qi Dianyuan
Test Engineer: Lin Hao
Testing Start Date: April 12, 2011
Testing End Date: April 12, 2011

1.4 Signature



Lin Hao

(Prepared this test report)



Qi Dianyuan

(Reviewed this test report)



Xiao Li

Deputy Director of the laboratory
(Approved this test report)

2 Client Information

2.1 Applicant Information

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 Telephone: 0086-021-61755257
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2.2 Manufacturer Information

Company Name: Huawei Technologies Co.,Ltd.
 Address /Post: Administration Building, Huawei Base, Bantian, Longgang District, Shenzhen 518129
 City: Shenzhen
 Postal Code: 518129
 Country: P. R. China
 Telephone: 0086-021-61755257
 Fax: 0086-021-61755612

3 Equipment Under Test (EUT) and Ancillary Equipment (AE)

3.1 About EUT

EUT Description: CDMA 1X Digital Mobile Phone with Bluetooth
 Model Name: M615
 Frequency Band: CDMA 835/1700/1880

3.2 Internal Identification of EUT used during the test

EUT ID*	SN or IMEI	HW Version	SW Version
EUT1	S9X9MB1130700208	Ver.B	M615C1TB106

*EUT ID: is used to identify the test sample in the lab internally.

3.3 Internal Identification of AE used during the test

AE ID*	Description	Model	SN	Manufacturer
AE1	Battery	HB5D1H	/	HUAWEI

*AE ID: is used to identify the test sample in the lab internally

4 CONDUCTED OUTPUT POWER MEASUREMENT

4.1 Summary

During the process of testing, the EUT was controlled via Rhode & Schwarz Digital Radio Communication tester (CMU-200) to ensure the maximum power transmission and proper modulation. This result contains conducted output power for the EUT. In all cases, the measured output power should be greater and within 5% than EMI measurement.

4.2 Conducted Power

CDMA 835MHz	Conducted Power (dBm)		
	Channel 777(848.31MHz)	Channel 384(836.52MHz)	Channel 1013(824.7MHz)
	24.4	24.5	24.4
CDMA 1700MHz	Conducted Power (dBm)		
	Channel 875(1753.75MHz)	Channel 450(1732.5MHz)	Channel 25(1711.25MHz)
	24.2	24.5	24.4
CDMA 1900MHz	Conducted Power (dBm)		
	Channel 1175(1908.75MHz)	Channel 600(1880MHz)	Channel 25(1851.25MHz)
	24.3	24.4	24.5

5. Reference Documents

5.1 Reference Documents for testing

The following document listed in this section is referred for testing.

Reference	Title	Version
ANSI C63.19-2007	American National Standard for Methods of Measurement of Compatibility between Wireless Communication Devices and Hearing Aids	2007 Edition
CTIA	CTIA_HAC_Test_Plan_Rev_2.0	2.0

6 OPERATIONAL CONDITIONS DURING TEST

6.1 HAC MEASUREMENT SET-UP

These measurements are performed using the DASY5 NEO automated dosimetric assessment system. It is made by Schmid & Partner Engineering AG (SPEAG) in Zurich, Switzerland. It consists of high precision robotics system (Stäubli), robot controller, Intel Core2 computer, near-field probe, probe alignment sensor. The robot is a six-axis industrial robot performing precise movements. A cell controller system contains the power supply, robot controller, teach pendant (Joystick), and remote control, is used to drive the robot motors. The PC consists of the HP Intel Core2 1.86 GHz computer with Windows XP system and HAC Measurement Software DASY5 NEO, A/D interface card, monitor, mouse, and keyboard. The Stäubli Robot is connected to the cell controller to allow software manipulation of the robot. A data acquisition electronic (DAE)

circuit performs the signal amplification, signal multiplexing, AD-conversion, offset measurements, mechanical surface detection, collision detection, etc. is connected to the Electro-optical coupler (EOC). The EOC performs the conversion from the optical into digital electric signal of the DAE and transfers data to the PC plug-in card.

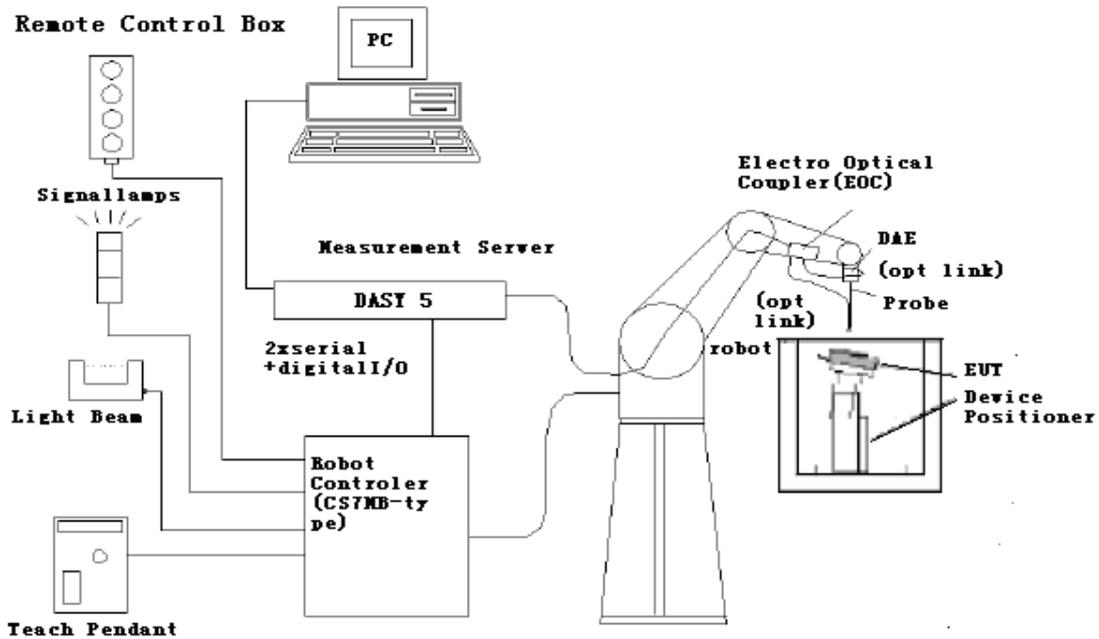


Fig. 1 HAC Test Measurement Set-up

The DAE4 consists of a highly sensitive electrometer-grade preamplifier with auto-zeroing, a channel and gain-switching multiplexer, a fast 16 bit AD-converter and a command decoder and control logic unit. Transmission to the PC-card is accomplished through an optical downlink for data and status information and an optical uplink for commands and clock lines. The mechanical probe mounting device includes two different sensor systems for frontal and sidewise probe contacts. They are also used for mechanical surface detection and probe collision detection. The robot uses its own controller with a built in VME-bus computer.

6.2 Probe Specification

6.2.1 E-Field Probe Description

Construction	One dipole parallel, two dipoles normal to probe axis Built-in shielding against static charges PEEK enclosure material
Calibration	In air from 100 MHz to 3.0 GHz (absolute accuracy $\pm 6.0\%$, $k=2$)
Frequency	40 MHz to > 6 GHz (can be extended to < 20 MHz) Linearity: ± 0.2 dB (100 MHz to 3 GHz)
Directivity	± 0.2 dB in air (rotation around probe axis) ± 0.4 dB in air (rotation normal to probe axis)
Dynamic Range	2 V/m to > 1000 V/m; Linearity: ± 0.2 dB



[ER3DV6]

Dimensions	Overall length: 330 mm (Tip: 16 mm) Tip diameter: 8 mm (Body: 12 mm) Distance from probe tip to dipole centers: 2.5 mm
Application	General near-field measurements up to 6 GHz Field component measurements Fast automatic scanning in phantoms

6.2.2 H-Field Probe Description

Construction	Three concentric loop sensors with 3.8 mm loop diameters Resistively loaded detector diodes for linear response Built-in shielding against static charges PEEK enclosure material (resistant to organic solvents, e.g., glycolether)
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[H3DV6]

Frequency	200 MHz to 3 GHz (absolute accuracy $\pm 6.0\%$, $k=2$); Output linearized
Directivity	± 0.2 dB (spherical isotropy error)
Dynamic Range	10 mA/m to 2 A/m at 1 GHz
E-Field Interference	< 10% at 3 GHz (for plane wave)
Dimensions	Overall length: 330 mm (Tip: 40 mm) Tip diameter: 6 mm (Body: 12 mm) Distance from probe tip to dipole centers: 3 mm
Application	General magnetic near-field measurements up to 3 GHz (in air or liquids) Field component measurements Surface current measurements Low interaction with the measured field

6.3 Test Arch Phantom & Phone Positioner

The Test Arch phantom should be positioned horizontally on a stable surface. Reference markings on the Phantom allow the complete setup of all predefined phantom positions and measurement grids by manually teaching three points in the robot. It enables easy and well defined positioning of the phone and validation dipoles as well as simple teaching of the robot (Dimensions: 370 x 370 x 370 mm).

The Phone Positioner supports accurate and reliable positioning of any phone with effect on near field $< \pm 0.5$ dB.

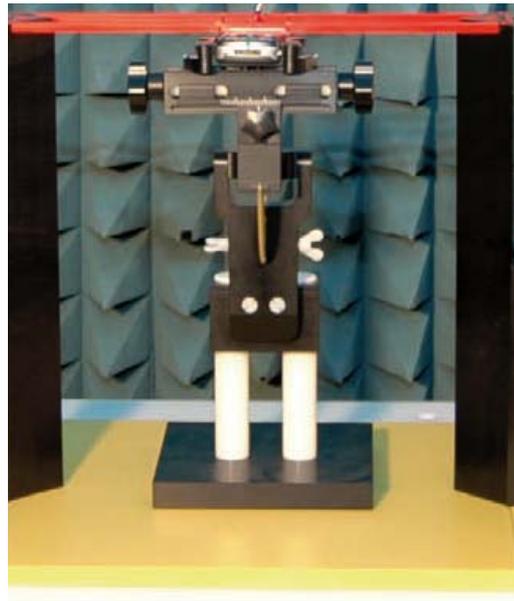


Fig. 2 HAC Phantom & Device Holder

6.4 Robotic System Specifications

Specifications

Positioner: Stäubli Unimation Corp. Robot Model: RX160L

Repeatability: ± 0.02 mm

No. of Axis: 6

Data Acquisition Electronic (DAE) System

Cell Controller

Processor: Intel Core2

Clock Speed: 1.86 GHz

Operating System: Windows XP

Data Converter

Features: Signal Amplifier, multiplexer, A/D converter, and control logic

Software: DASY5 software

Connecting Lines: Optical downlink for data and status info.

Optical uplink for commands and clock

7 EUT ARRANGEMENT

7.1 WD RF Emission Measurements Reference and Plane

Figure 4 illustrates the references and reference plane that shall be used in the WD emissions measurement.

- The grid is 5 cm by 5 cm area that is divided into 9 evenly sized blocks or sub-grids.
- The grid is centered on the audio frequency output transducer of the WD (speaker or T-coil).
- The grid is located by reference to a reference plane. This reference plane is the planar area that contains the highest point in the area of the WD that normally rests against the user's ear
- The measurement plane is located parallel to the reference plane and 10 mm from it, out from

the phone. The grid is located in the measurement plane.

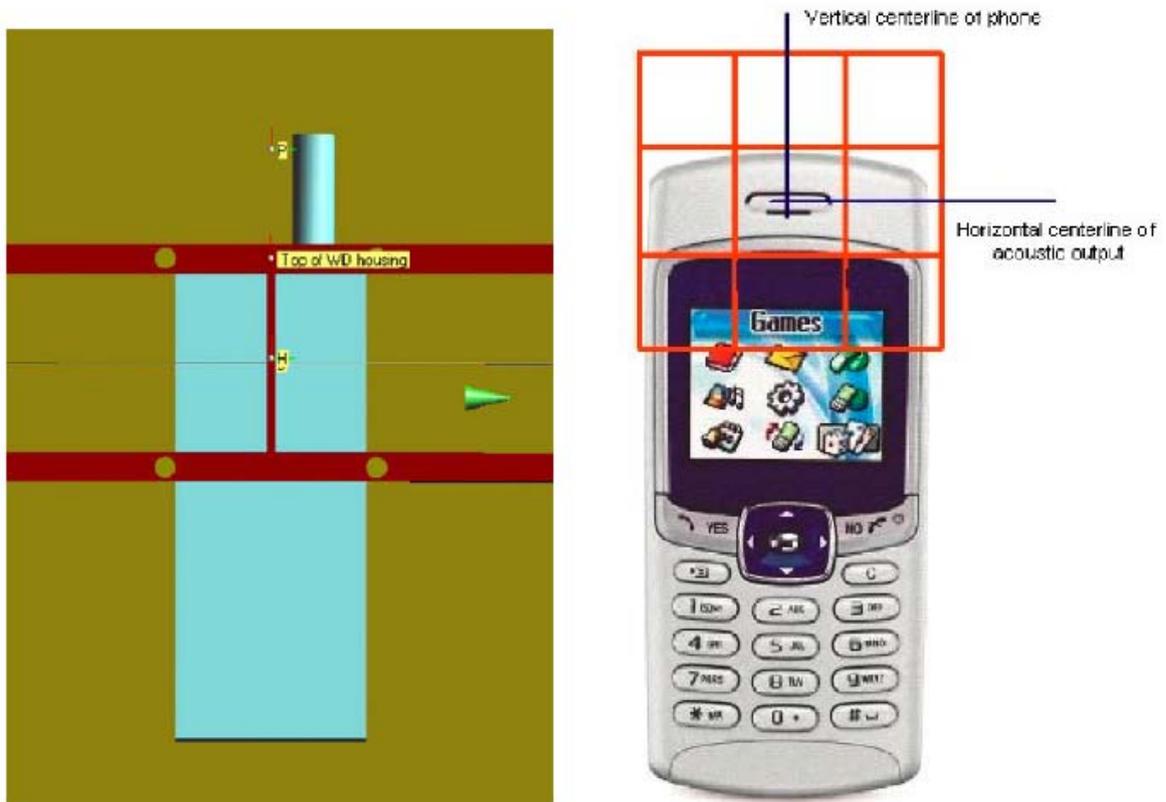


Fig. 3 WD reference and plane for RF emission measurements

8 SYSTEM VALIDATION

8.1 Validation Procedure

Place a dipole antenna meeting the requirements given in ANSI C63.19 D.5 in the position normally occupied by the WD. The dipole antenna serves as a known source for an electrical and magnetic output. Position the E-field and H-field probes so that:

- The probes and their cables are parallel to the coaxial feed of the dipole antenna
- The probe cables and the coaxial feed of the dipole antenna approach the measurement area from opposite directions
- The center point of the probe element(s) are 10 mm from the closest surface of the dipole elements.

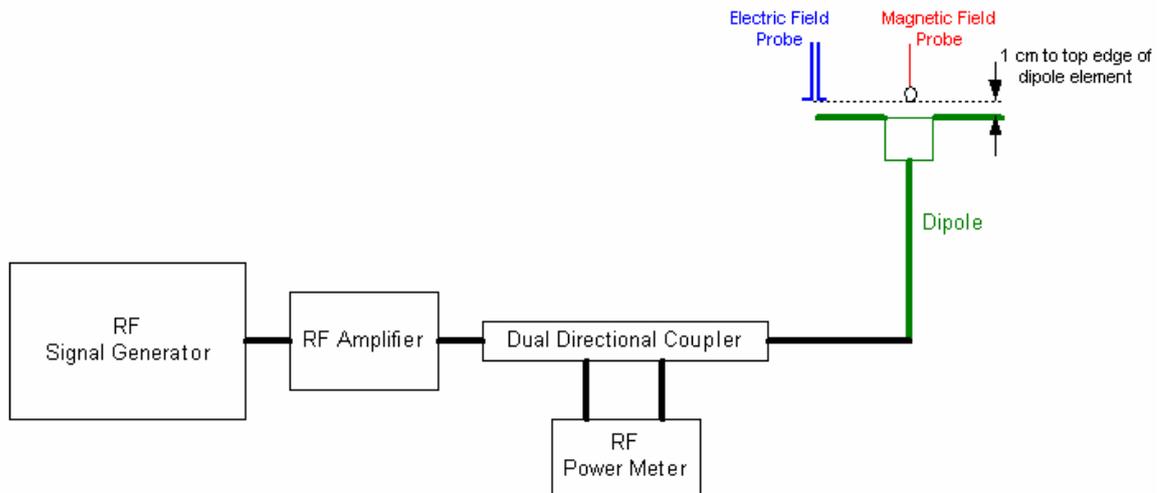


Fig. 4 Dipole Validation Setup

8.2 Validation Result

E-Field Scan							
Mode	Frequency (MHz)	Input Power (mW)	Power	Measured ¹ Value(V/m)	Target ² Value(V/m)	Deviation ³ (%)	Limit ⁴ (%)
CW	835	100		170.3	163.9	+3.90%	± 25
CW	1880	100		132.7	137.7	-3.63%	± 25
H-Field Scan							
Mode	Frequency (MHz)	Input Power (mW)	Power	Measured Value(A/m)	Target Value(A/m)	Deviation (%)	Limit (%)
CW	835	100		0.441	0.458	-3.71%	± 25
CW	1880	100		0.445	0.463	-3.89%	± 25

Notes:

1. Please refer to the attachment for detailed measurement data and plot.
2. Target value is provided by SPEAD in the calibration certificate of specific dipoles.
3. Deviation (%) = 100 * (Measured value minus Target value) divided by Target value.
4. ANSI C63.19 requires values within ± 25% are acceptable, of which 12% is deviation and 13% is measurement uncertainty. Values independently validated for the dipole actually used in the measurements should be used, when available.

9 Probe Modulation Factor

The Probe Modulation Factor (PMF) is defined as the ratio of the field readings for a CW and a modulated signal with the equivalent Field Envelope Peak as defined in ANSI C63.19 (Chapter C.3.1). Calibration shall be made of the modulation response of the probe and its instrumentation chain. This Calibration shall be performed with the field probe, attached to the instrumentation that is to be used with it during the measurement. The response of the probe system to a CW field at the frequency(s) of interest is compared to its response to a modulated signal with equal peak amplitude. The field level of the test signals shall be more than 10dB above the ambient level and

the noise floor of the instrumentation being used. The ratio of the CW reading to that taken with a modulated field shall be applied to the readings taken of modulated fields of the specified type.

Note:

For the PMF of CDMA835/1880, we need to calculate it at CDMA SO55 and SO3 respectively according to CTIA request.

9.1 Modulation Factor Test Procedure

This may be done using the following procedure:

1. Fix the field probe in a set location relative to a field generating device, such as the reference dipole antenna, as illustrated in the following figure.
2. Illuminate the probe using the wireless device (EUT) connected to the reference dipole with a test signal at the intended measurement frequency, Ensure there is sufficient field coupling between the probe and the antenna so the resulting reading is greater than 10 dB above the probe system noise floor but within the systems operating range.

Note:

- The EUT shall be placed on a Service Option 3 call using Radio Configuration 1. The EUT audio shall be muted such that the RF gating is guaranteed to be 1/8th rate.

- The EUT shall be placed on a Service Option 2 or Service Option 55 call using Radio Configuration 1. The data rate shall be set to "Full".

- The test shall be run in Cell Band and PCS Band at low, mid, and high channels. Cell Band test channels shall be 1013, 384, and 777. PCS Band test channels shall be 25, 600, and 1175.

3. Record the amplitude applied to the antenna during transmission and the field strength measured by the E-field probe located near the tip of the dipole antenna
4. Replace the wireless device with an RF signal generator producing an unmodulated CW signal and set to the wireless device operating frequency.
5. Set the amplitude of the unmodulated signal to equal that recorded from the wireless device.
6. Record the reading of the probe measurement system of the unmodulated signal.
7. The ratio, in linear units, of the probe reading in Step 6) to the reading in Step 3) is the E-field modulation factor. $PMF_E = E_{CW} / E_{mod}$ ($PMF_H = H_{CW} / H_{mod}$)
8. Repeat the previous steps using the H-field probe, except locate the probe at the center of the dipole.

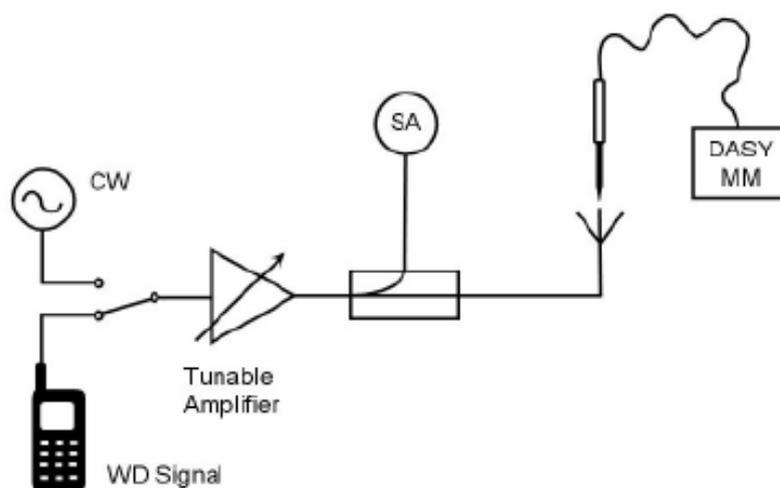


Fig. 6 Probe Modulation Factor Test Setup

9.2 Modulation Factor

9.2.1 E-Field

Mode	Frequency (MHz)	E-Field Measured Value (V/m)	Probe Modulation Factor
CW	848.31	258	0.942
CDMA(SO55)		274	
CW	836.52	247	0.928
CDMA(SO55)		266	
CW	824.7	240	0.934
CDMA(SO55)		257	
CW	848.31	34.22	2.92
CDMA(SO3)		11.72	
CW	836.52	34.78	2.89
CDMA(SO3)		12.03	
CW	824.7	34.64	2.91
CDMA(SO3)		11.90	
CW	1908.75	174	0.935
CDMA(SO55)		186	
CW	1880	178	0.967
CDMA(SO55)		184	
CW	1851.25	171	0.950
CDMA(SO55)		180	
CW	1908.75	42.96	2.91
CDMA(SO3)		14.78	
CW	1880	43.07	2.89
CDMA(SO3)		14.91	
CW	1851.25	42.41	2.92
CDMA(SO3)		14.50	
CW	1700	137.7	1.00
CDMA		137.5	

9.2.2 H-Field

Mode	Frequency (MHz)	H-Field Measured Value (A/m)	Probe Modulation Factor
CW	848.31	0.571	0.909
CDMA(SO55)		0.628	
CW	836.52	0.563	0.891
CDMA(SO55)		0.632	
CW	824.7	0.560	0.896
CDMA(SO55)		0.625	
CW	848.31	0.289	2.86
CDMA(SO3)		0.101	
CW	836.52	0.301	2.92
CDMA(SO3)		0.103	

CW	824.7	0.304	2.92
CDMA(SO3)		0.104	
CW	1908.75	0.465	0.965
CDMA(SO55)		0.482	
CW	1880	0.473	0.920
CDMA(SO55)		0.514	
CW	1851.25	0.491	0.926
CDMA(SO55)		0.530	
CW	1908.75	0.241	2.94
CDMA(SO3)		0.082	
CW	1880	0.244	2.97
CDMA(SO3)		0.082	
CW	1851.25	0.235	2.97
CDMA(SO3)		0.079	
CW	1700	0.463	1.00
CDMA		0.461	

10 RF TEST PROCEDURES

The evaluation was performed with the following procedure:

- 1) Confirm proper operation of the field probe, probe measurement system and other instrumentation and the positioning system.
- 2) Position the WD in its intended test position. The gauge block can simplify this positioning. Note that a separate E-field and H-field gauge block will be needed if the center of the probe sensor elements are at different distances from the tip of the probe.
- 3) Configure the WD normal operation for maximum rated RF output power, at the desired channel and other operating parameters (e.g., test mode), as intended for the test.
- 4) The center sub-grid shall centered on the center of the T-Coil mode axial measurement point or the acoustic output, as appropriate. Locate the field probe at the initial test position in the 50 mm by 50 mm grid, which is contained in the measurement plane. If the field alignment method is used, align the probe for maximum field reception.
- 5) Record the reading.
- 6) Scan the entire 50 mm by 50 mm region in equally spaced increments and record the reading at each measurement point. The distance between measurement points shall be sufficient to assure the identification of the maximum reading.
- 7) Identify the five contiguous sub-grids around the center sub-grid with the lowest maximum field strength readings. Thus the six areas to be used to determine the WD's highest emissions are identified and outlined for the final manual scan. Please note that a maximum of five blocks can be excluded for both E-field and H-field measurements for the WD output being measured. Stated another way, the center sub-grid and three others must be common to both the E-field and H-field measurements.
- 8) Identify the maximum field reading within the non-excluded sub-grids identified in Step 7)
- 9) Convert the maximum field strength reading identified in Step 8) to V/m or A/m, as appropriate. For probes which require a probe modulation factor, this conversion shall be done using the

appropriate probe modulation factor and the calibration.

10) Repeat Step 1) through Step 10) for both the E-field and H-field measurements.

11) Compare this reading to the categories in ANSI C63.19 Clause 7 and record the resulting category. The lowest category number listed in 7.2, Table 7.4, or Table 7.5 obtained in Step 10) for either E- or H-field determines the M category for the audio coupling mode assessment. Record the WD category rating.

11 HAC RF TEST DATA SUMMARY

11.1 Measurement Results (E-Field)

Frequency		AWF	Measured Value (V/m)	Power Drift (dB)	Category
MHz	Channel				
CDMA 1700					
1753.75	875	0	47.5	0.047	M4 (see Fig B.1)
1732.5	450	0	45.7	0.071	M4 (see Fig B.2)
1711.25	25	0	42.2	-0.043	M4 (see Fig B.3)

CDMA Mode: SO55

Frequency		AWF	Measured Value (V/m)	Power Drift (dB)	Category
MHz	Channel				
CDMA 835					
848.31	777	0	70.7	0.056	M4 (see Fig B.4)
836.52	384	0	73.1	0.020	M4 (see Fig B.5)
824.7	1013	0	67.9	0.189	M4 (see Fig B.6)
CDMA 1880					
1908.75	1175	0	44.1	0.049	M4 (see Fig B.7)
1880	600	0	44.7	-0.151	M4 (see Fig B.8)
1851.25	25	0	45.9	0.137	M4 (see Fig B.9)

CDMA Mode: SO3

Frequency		AWF	Measured Value (V/m)	Power Drift (dB)	Category
MHz	Channel				
CDMA 835					
848.31	777	0	75.8	-0.125	M4 (see Fig B.10)
836.52	384	0	78.4	0.006	M4 (see Fig B.11)
824.7	1013	0	73.9	-0.026	M4 (see Fig B.12)
CDMA 1880					
1908.75	1175	0	46.2	-0.097	M4 (see Fig B.13)
1880	600	0	62.6	-0.178	M4 (see Fig B.14)
1851.25	25	0	50.7	0.051	M4 (see Fig B.15)

11.2 Measurement Results (H-Field)

Frequency		AWF	Measured Value (A/m)	Power Drift (dB)	Category
MHz	Channel				
CDMA 1700					
1753.75	875	0	0.117	0.074	M4(see Fig B.16)
1732.5	450	0	0.112	-0.021	M4(see Fig B.17)
1711.25	25	0	0.111	0.00907	M4(see Fig B.18)

CDMA Mode: SO55

Frequency		AWF	Measured Value (A/m)	Power Drift (dB)	Category
MHz	Channel				
CDMA 835					
848.31	777	0	0.106	0.064	M4(see Fig B.19)
836.52	384	0	0.104	-0.037	M4(see Fig B.20)
824.7	1013	0	0.099	-0.113	M4(see Fig B.21)
CDMA 1880					
1908.75	1175	0	0.115	-0.047	M4(see Fig B.22)
1880	600	0	0.108	-0.030	M4(see Fig B.23)
1851.25	25	0	0.116	-0.173	M4(see Fig B.24)

CDMA Mode: SO3

Frequency		AWF	Measured Value (A/m)	Power Drift (dB)	Category
MHz	Channel				
CDMA 835					
848.31	777	0	0.165	0.059	M4(see Fig B.25)
836.52	384	0	0.159	-0.101	M4(see Fig B.26)
824.7	1013	0	0.116	0.118	M4(see Fig B.27)
CDMA 1880					
1908.75	1175	0	0.189	0.101	M4(see Fig B.28)
1880	600	0	0.162	0.054	M4(see Fig B.29)
1851.25	25	0	0.219	0.022	M4(see Fig B.30)

11.3 Total M-rating

Mode	Maximum value of peak Total E-Field (V/m)	Maximum value of peak Total H-Field (A/m)	E-Field M Rating	H-Field M Rating	Total M Rating
CDMA 1700	47.5	0.117	M4 (AWF 0 dB)	M4 (AWF 0 dB)	M4(see Fig B.31)

CDMA Mode: SO55

Mode	Maximum value of peak Total E-Field (V/m)	Maximum value of peak Total H-Field (A/m)	E-Field M Rating	H-Field M Rating	Total M Rating
CDMA 835	73.1	0.106	M4 (AWF 0 dB)	M4 (AWF 0 dB)	M4(see Fig B.32)

CDMA 1880	45.9	0.116	M4 (AWF 0 dB)	M4 (AWF 0 dB)	M4(see Fig B.33)
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CDMA Mode: SO3

Mode	Maximum value of peak Total E-Field (V/m)	Maximum value of peak Total H-Field (A/m)	E-Field M Rating	H-Field M Rating	Total M Rating
CDMA 835	78.4	0.165	M4 (AWF 0 dB)	M4 (AWF 0 dB)	M4(see Fig B.34)
CDMA 1880	62.6	0.219	M4 (AWF 0 dB)	M4 (AWF 0 dB)	M4(see Fig B.35)

12 ANSI C 63.19-2006 LIMITS

Table 1: Telephone near-field categories in linear units

Category		Telephone RF parameters < 960 MHz			
Near field	AWF	E-field emissions		H-field emissions	
Category M1/T1	0	631.0 to 1122.0	V/m	1.91 to 3.39	A/m
	-5	473.2 to 841.4	V/m	1.43 to 2.54	A/m
Category M2/T2	0	354.8 to 631.0	V/m	1.07 to 1.91	A/m
	-5	266.1 to 473.2	V/m	0.80 to 1.43	A/m
Category M3/T3	0	199.5 to 354.8	V/m	0.60 to 1.07	A/m
	-5	149.6 to 266.1	V/m	0.45 to 0.80	A/m
Category M4/T4	0	< 199.5	V/m	< 0.60	A/m
	-5	< 149.6	V/m	< 0.45	A/m
Category		Telephone RF parameters > 960 MHz			
Near field	AWF	E-field emissions		H-field emissions	
Category M1/T1	0	199.5 to 354.8	V/m	0.60 to 1.07	A/m
	-5	149.6 to 266.1	V/m	0.45 to 0.80	A/m
Category M2/T2	0	112.2 to 199.5	V/m	0.34 to 0.60	A/m
	-5	84.1 to 149.6	V/m	0.25 to 0.45	A/m
Category M3/T3	0	63.1 to 112.2	V/m	0.19 to 0.34	A/m
	-5	47.3 to 84.1	V/m	0.14 to 0.25	A/m
Category M4/T4	0	< 63.1	V/m	< 0.19	A/m
	-5	< 47.3	V/m	< 0.14	A/m

13 MEASUREMENT UNCERTAINTY

No.	Error source	Type	Uncertainty Value (%)	Prob. Dist.	k	c_i E	c_i H	Standard Uncertainty (%) u_i' (%) E	Standard Uncertainty (%) u_i' (%) H	Degree of freedom V_{eff} or ν_i
1	System repeatability	A	0.24	N	1	1	1	0.24	0.24	9
Measurement System										
2	– Probe Calibration	B	3	N	1	1	1	5.1	5.1	∞
3	– Axial Isotropy	B	3.5	R	$\sqrt{3}$	1	1	2.7	2.7	∞
4	– Sensor Displacement	B	16.5	R	$\sqrt{3}$	1	0.145	9.5	1.4	∞
5	– Boundary Effects	B	2.4	R	$\sqrt{3}$	1	1	1.4	1.4	∞
6	– Linearity	B	4.7	R	$\sqrt{3}$	1	1	2.7	2.7	∞
7	– Scaling to Peak Envelope Power	B	2.0	R	$\sqrt{3}$	1	1	1.2	1.2	∞
8	– System Detection Limit	B	1.0	R	$\sqrt{3}$	1	1	0.6	0.6	∞
9	– Readout Electronics	B	0.3	N	1	1	1	0.3	0.3	∞
10	- Response Time	B	0.8	R	$\sqrt{3}$	1	1	0.5	0.5	∞
11	– Integration Time	B	2.6	R	$\sqrt{3}$	1	1	1.5	1.5	∞
12	– RF Ambient Conditions	B	3.0	R	$\sqrt{3}$	1	1	1.7	1.7	∞
13	– RF Reflections	B	12.0	R	$\sqrt{3}$	1	1	6.9	6.9	∞
14	– Probe Positioner	A	1.2	R	$\sqrt{3}$	1	0.67	0.7	0.5	∞
15	– Probe Positioning	A	4.7	R	$\sqrt{3}$	1	0.67	2.7	1.8	∞
16	– Extra. And Interpolation	B	1.0	R	$\sqrt{3}$	1	1	0.6	0.6	∞
Test Sample Related										
17	– Device Positioning Vertical	B	4.7	R	$\sqrt{3}$	1	0.67	2.7	1.8	∞
18	– Device Positioning Lateral	B	1.0	R	$\sqrt{3}$	1	1	0.6	0.6	∞

19	– Device Holder and Phantom	B	2.4	R	$\sqrt{3}$	1	1	1.4	1.4	∞	
20	– Power Drift	B	5.0	R	$\sqrt{3}$	1	1	2.9	2.9	∞	
Phantom and Setup related											
21	– Phantom Thickness	B	2.4	R	$\sqrt{3}$	1	0.67	1.4	0.9	∞	
PMF											
22	– monitoring amplitude ratio	B	2.8	R	$\sqrt{3}$	1	1	1.6	1.6	∞	
23	– setup repeatability	A	2.7	N	1	1	1	2.7	2.7	9	
24	– sensor amplitude	B	11.6	R	$\sqrt{3}$	1	0.569	6.7	3.8	∞	
Combined standard uncertainty (%)		$u_c' = \sqrt{\sum_{i=1}^{24} c_i^2 u_i^2}$						16.4	11.5		
Expanded uncertainty (confidence interval of 95 %)		$u_e = 2u_c$		N		k=2		32.8	23.0		

14 MAIN TEST INSTRUMENTS

Table 2: List of Main Instruments

No.	Name	Type	Serial Number	Calibration Date	Valid Period
01	E-Field Probe	ER3DV6	2428	October 20, 2010	One year
02	H-Field Probe	H3DV6	6260	October 20, 2010	One year
03	HAC Dipole	CD835V3	1023	October 21, 2009	Two years
04	HAC Dipole	CD1880V3	1018	October 21, 2009	Two years
05	BTS	8960	MY48365192	November 18, 2010	One year
06	DAE	SPEAG DAE4	777	July 9, 2010	One year

15 CONCLUSION

The HAC measurement indicates that the EUT complies with the HAC limits of the ANSI C63.19-2007. The total M-rating is **M4** for CDMA 835/1700/1880 band.

END OF REPORT BODY

ANNEX A TEST LAYOUT**Picture A1: HAC RF System Layout**

ANNEX B TEST PLOTS

HAC RF E-Field CDMA 1700 High

Date/Time: 4/12/2011 10:06:03 AM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 23.3°C Liquid Temperature: 22.5°C

Communication System: CDMA 1700; Frequency: 1753.75 MHz; Duty Cycle: 1:1

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1)

E Scan - ER3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 47.5 V/m

Probe Modulation Factor = 1

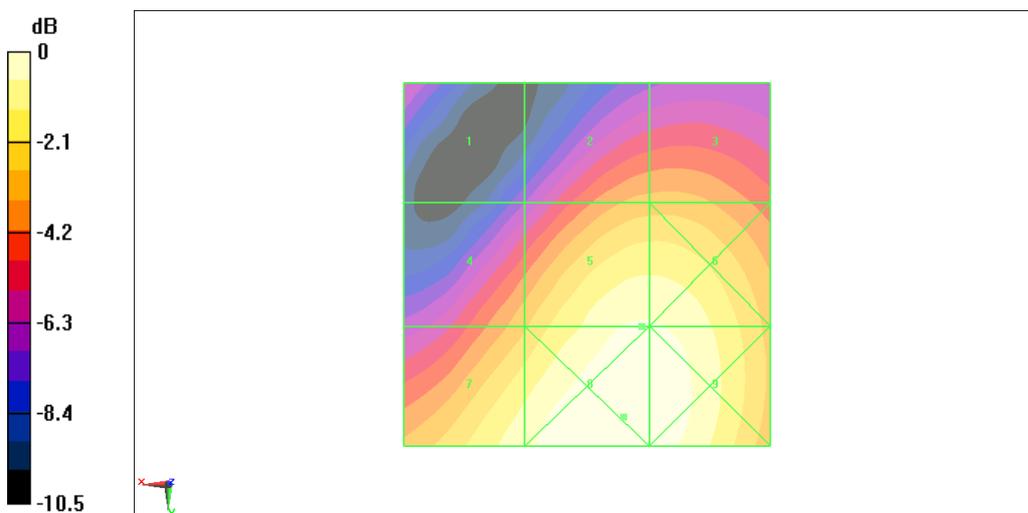
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 48.7 V/m; Power Drift = 0.047 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
25.7 M4	35.3 M4	35.5 M4
Grid 4	Grid 5	Grid 6
36.6 M4	47.5 M4	47.5 M4
Grid 7	Grid 8	Grid 9
46.1 M4	51 M4	50.4 M4



0 dB = 51V/m

Fig B.1 HAC RF E-Field CDMA 1700 High

HAC RF E-Field CDMA 1700 Middle

Date/Time: 4/12/2011 10:11:24 AM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 23.3°C Liquid Temperature: 22.5°C

Communication System: CDMA 1700; Frequency: 1732.5 MHz; Duty Cycle: 1:1

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1)

E Scan - ER3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 45.7 V/m

Probe Modulation Factor = 1

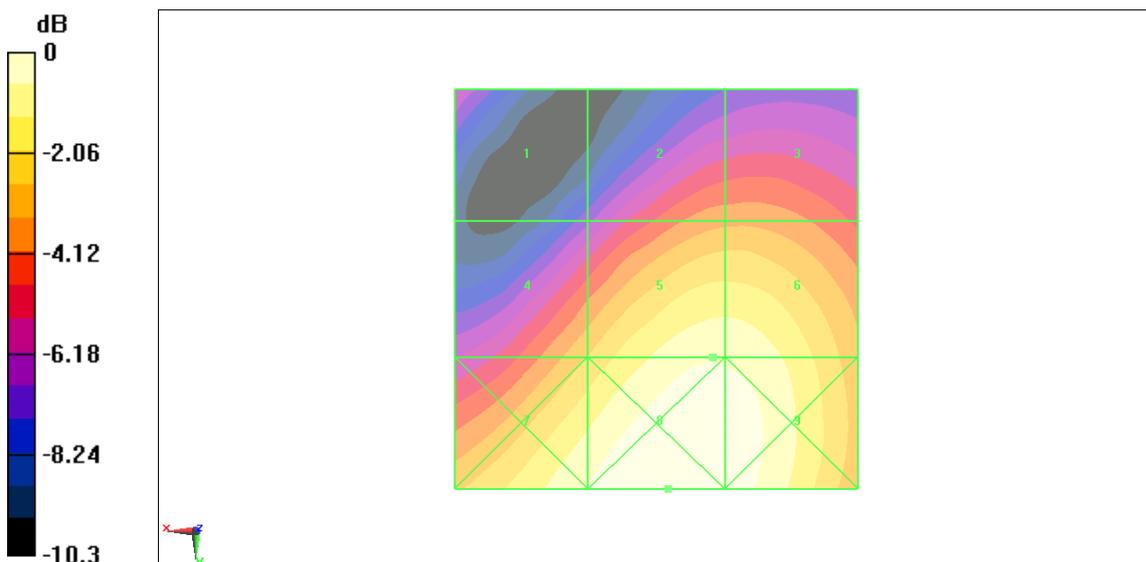
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 46.2 V/m; Power Drift = 0.071 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 24.9 M4	Grid 2 32.9 M4	Grid 3 33.1 M4
Grid 4 36.5 M4	Grid 5 45.7 M4	Grid 6 45.6 M4
Grid 7 46.3 M4	Grid 8 49.9 M4	Grid 9 48.9 M4



0 dB = 49.9V/m

Fig B.2 HAC RF E-Field CDMA 1700 Middle

HAC RF E-Field CDMA 1700 Low

Date/Time: 4/12/2011 10:17:14 AM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 23.3°C Liquid Temperature: 22.5°C

Communication System: CDMA 1700; Frequency: 1711.25 MHz; Duty Cycle: 1:1

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1)

E Scan - ER3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 42.2 V/m

Probe Modulation Factor = 1

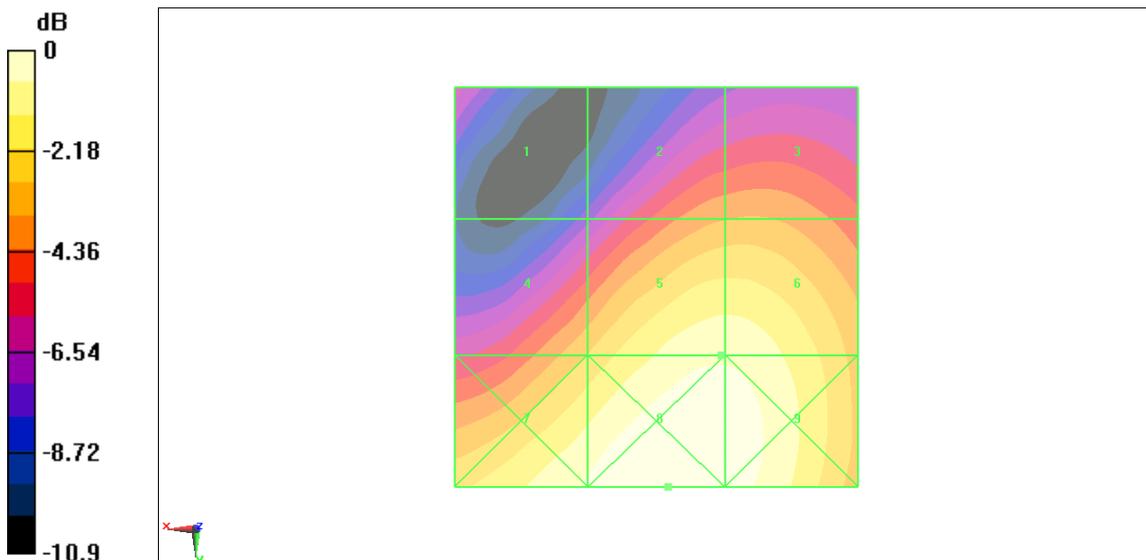
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 42.6 V/m; Power Drift = -0.043 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 23.2 M4	Grid 2 30.6 M4	Grid 3 30.9 M4
Grid 4 33.5 M4	Grid 5 42.2 M4	Grid 6 42.2 M4
Grid 7 43.4 M4	Grid 8 46.5 M4	Grid 9 45.2 M4



0 dB = 46.5V/m

Fig B.3 HAC RF E-Field CDMA 1700 Low

HAC RF E-Field CDMA 835 High – SO55

Date/Time: 4/12/2011 4:40:56 PM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 23.3°C Liquid Temperature: 22.5°C

Communication System: CDMA 835; Frequency: 848.31 MHz; Duty Cycle: 1:1

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1)

E Scan - ER3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 70.7 V/m

Probe Modulation Factor = 0.935

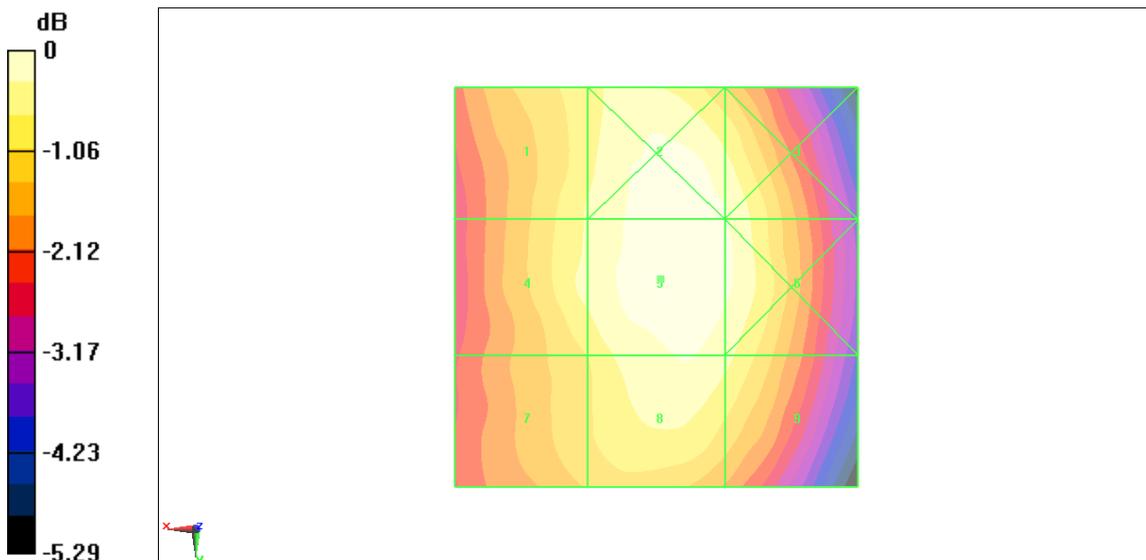
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 97.5 V/m; Power Drift = 0.056 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
65.5 M4	69.6 M4	68.2 M4
Grid 4	Grid 5	Grid 6
66.2 M4	70.7 M4	68.6 M4
Grid 7	Grid 8	Grid 9
62.8 M4	68.1 M4	66.1 M4



0 dB = 70.7V/m

Fig B.4 HAC RF E-Field CDMA 835 High

HAC RF E-Field CDMA 835 Middle – SO55

Date/Time: 4/12/2011 4:46:34 PM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 23.3°C Liquid Temperature: 22.5°C

Communication System: CDMA 835; Frequency: 836.52 MHz; Duty Cycle: 1:1

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1)

E Scan - ER3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 73.1 V/m

Probe Modulation Factor = 0.939

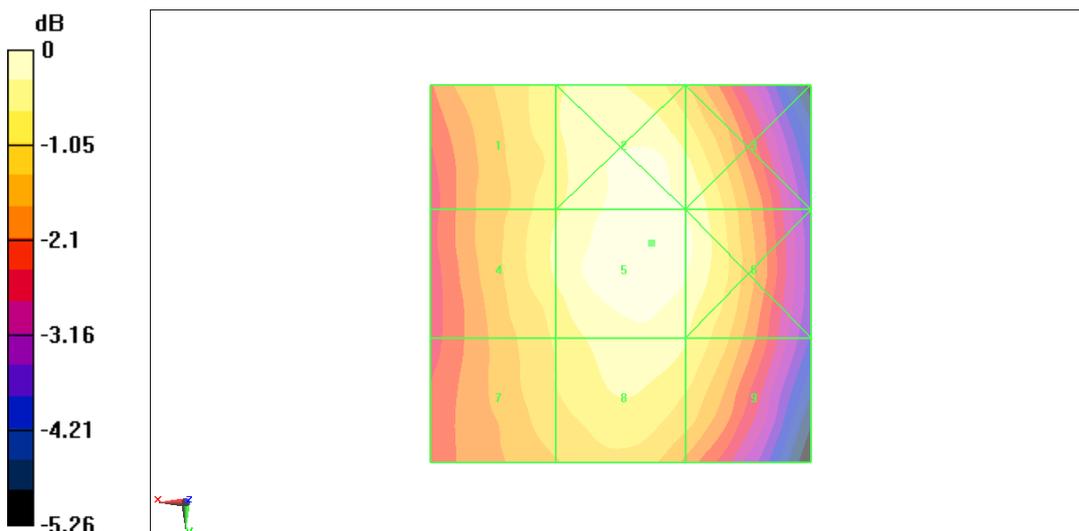
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 100.4 V/m; Power Drift = 0.020 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 67.1 M4	Grid 2 71.7 M4	Grid 3 70.2 M4
Grid 4 68 M4	Grid 5 73.1 M4	Grid 6 71 M4
Grid 7 65.2 M4	Grid 8 69.8 M4	Grid 9 67.7 M4



0 dB = 73.1V/m

Fig B.5 HAC RF E-Field CDMA 835 Middle

HAC RF E-Field CDMA 835 Low – SO55

Date/Time: 4/12/2011 4:52:36 PM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 23.3°C Liquid Temperature: 22.5°C

Communication System: CDMA 835; Frequency: 824.7 MHz; Duty Cycle: 1:1

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1)

E Scan - ER3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 67.9 V/m

Probe Modulation Factor = 0.938

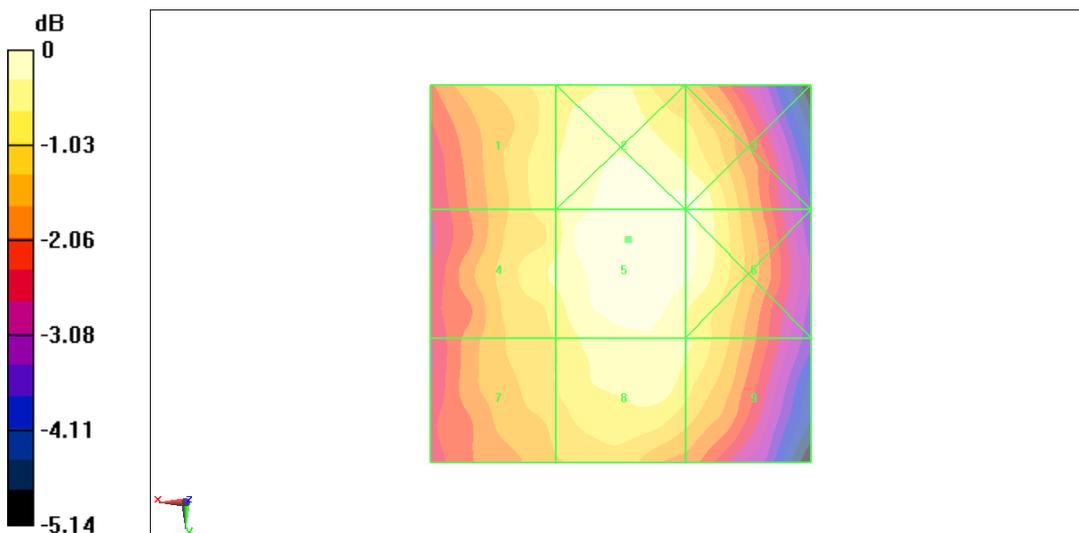
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 93.5 V/m; Power Drift = 0.189 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 62.8 M4	Grid 2 67.3 M4	Grid 3 66.2 M4
Grid 4 63.3 M4	Grid 5 67.9 M4	Grid 6 66.3 M4
Grid 7 60.5 M4	Grid 8 65.1 M4	Grid 9 63.3 M4



0 dB = 67.9V/m

Fig B.6 HAC RF E-Field CDMA 835 Low

HAC RF E-Field CDMA 1900 High – SO55

Date/Time: 4/12/2011 9:48:56 AM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 23.3°C Liquid Temperature: 22.5°C

Communication System: CDMA 1900; Frequency: 1908.75 MHz; Duty Cycle: 1:1

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1)

E Scan - ER3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 44.1 V/m

Probe Modulation Factor = 0.952

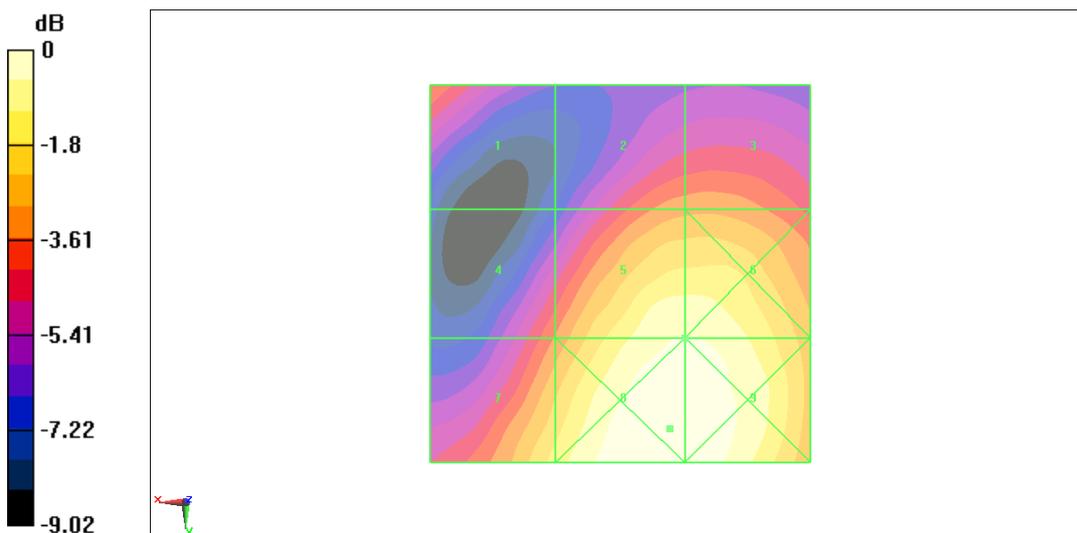
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 46.2 V/m; Power Drift = 0.049 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 31.4 M4	Grid 2 32.7 M4	Grid 3 33 M4
Grid 4 31.4 M4	Grid 5 44.1 M4	Grid 6 44.1 M4
Grid 7 39.4 M4	Grid 8 47.1 M4	Grid 9 47 M4



0 dB = 47.1V/m

Fig B.7 HAC RF E-Field CDMA 1900 High

HAC RF E-Field CDMA 1900 Middle – SO55

Date/Time: 4/12/2011 9:54:19 AM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 23.3°C Liquid Temperature: 22.5°C

Communication System: CDMA 1900; Frequency: 1880 MHz; Duty Cycle: 1:1

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1)

E Scan - ER3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 44.7 V/m

Probe Modulation Factor = 0.956

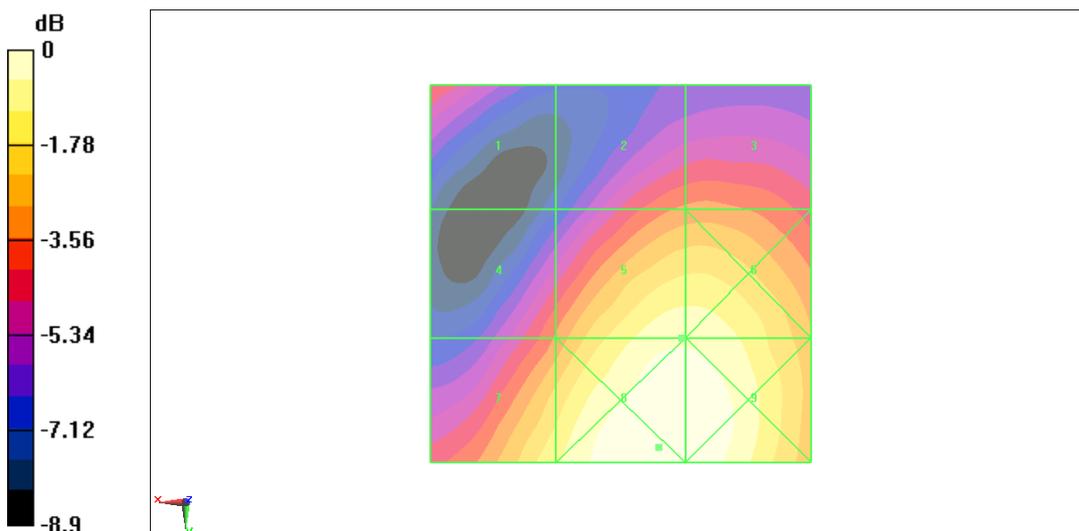
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 46.7 V/m; Power Drift = -0.151 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 30.6 M4	Grid 2 32.8 M4	Grid 3 33.2 M4
Grid 4 32.6 M4	Grid 5 44.7 M4	Grid 6 44.7 M4
Grid 7 41.9 M4	Grid 8 48.5 M4	Grid 9 48.2 M4



0 dB = 48.5V/m

Fig B.8 HAC RF E-Field CDMA 1900 Middle

HAC RF E-Field CDMA 1900 Low – SO55

Date/Time: 4/12/2011 9:59:48 AM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 23.3°C Liquid Temperature: 22.5°C

Communication System: CDMA 1900; Frequency: 1851.25 MHz; Duty Cycle: 1:1

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1)

E Scan - ER3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 45.9 V/m

Probe Modulation Factor = 0.945

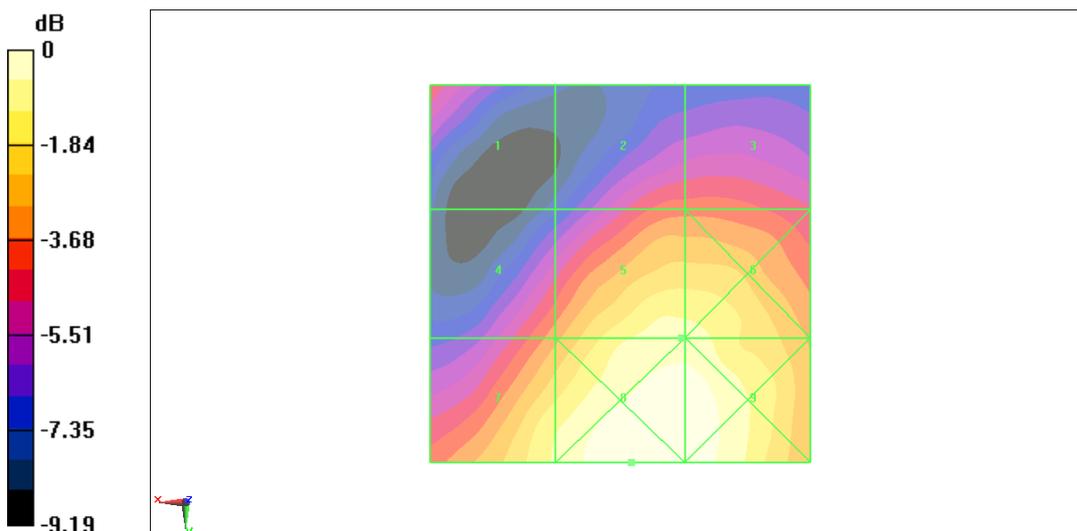
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 47.8 V/m; Power Drift = 0.137 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 31 M4	Grid 2 32.5 M4	Grid 3 32.6 M4
Grid 4 35.1 M4	Grid 5 45.9 M4	Grid 6 45.9 M4
Grid 7 44.8 M4	Grid 8 51 M4	Grid 9 49.7 M4



0 dB = 51V/m

Fig B.9 HAC RF E-Field CDMA 1900 Low

HAC RF E-Field CDMA 835 High – SO3

Date/Time: 4/12/2011 4:21:34 PM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 23.3°C Liquid Temperature: 22.5°C

Communication System: CDMA 835; Frequency: 848.31 MHz; Duty Cycle: 1:1

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1)

E Scan - ER3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 75.8 V/m

Probe Modulation Factor = 2.91

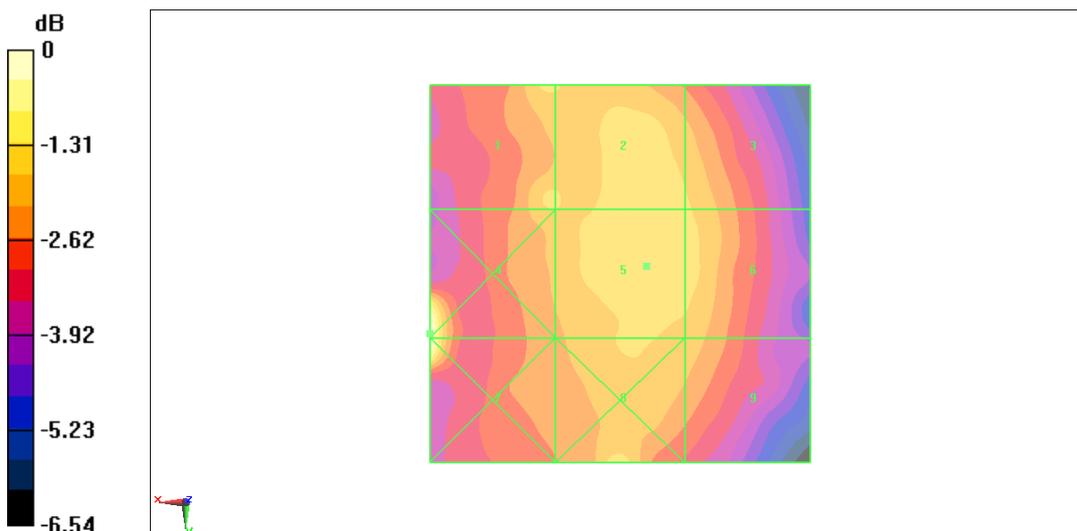
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 36 V/m; Power Drift = -0.125 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 73.9 M4	Grid 2 75.7 M4	Grid 3 73.6 M4
Grid 4 89 M4	Grid 5 75.8 M4	Grid 6 74.6 M4
Grid 7 88.6 M4	Grid 8 74.5 M4	Grid 9 71.6 M4



0 dB = 89V/m

Fig B.10 HAC RF E-Field CDMA 835 High

HAC RF E-Field CDMA 835 Middle – SO3

Date/Time: 4/12/2011 4:27:19 PM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 23.3°C Liquid Temperature: 22.5°C

Communication System: CDMA 835; Frequency: 836.52 MHz; Duty Cycle: 1:1

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1)

E Scan - ER3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 78.4 V/m

Probe Modulation Factor = 2.89

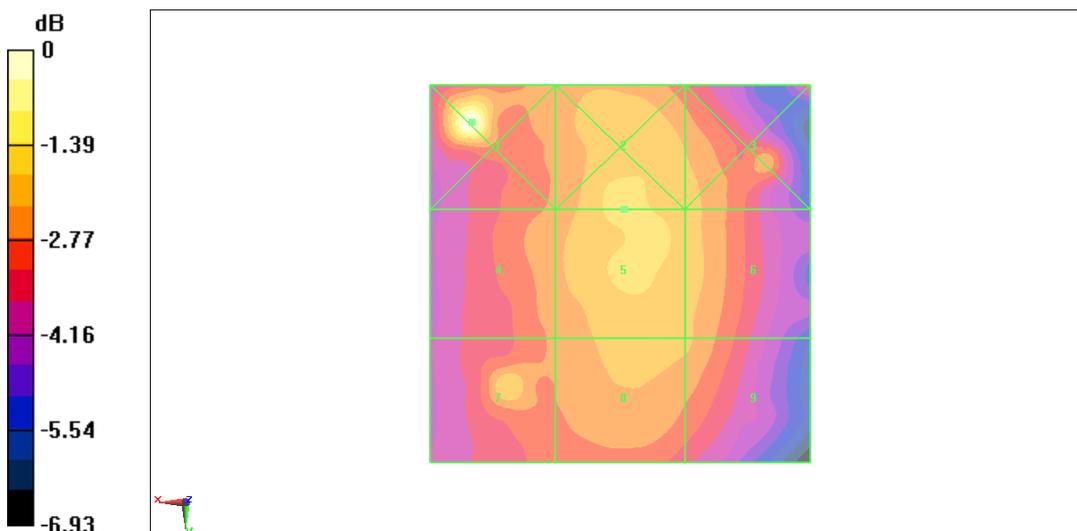
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 33.9 V/m; Power Drift = 0.006 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
93.8 M4	78.9 M4	73.9 M4
Grid 4	Grid 5	Grid 6
71.3 M4	78.4 M4	74.4 M4
Grid 7	Grid 8	Grid 9
75.9 M4	74.2 M4	72.7 M4



0 dB = 93.8V/m

Fig B.11 HAC RF E-Field CDMA 835 Middle

HAC RF E-Field CDMA 835 Low – SO3

Date/Time: 4/12/2011 4:33:21 PM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 23.3°C Liquid Temperature: 22.5°C

Communication System: CDMA 835; Frequency: 824.7 MHz; Duty Cycle: 1:1

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1)

E Scan - ER3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 73.9 V/m

Probe Modulation Factor = 2.91

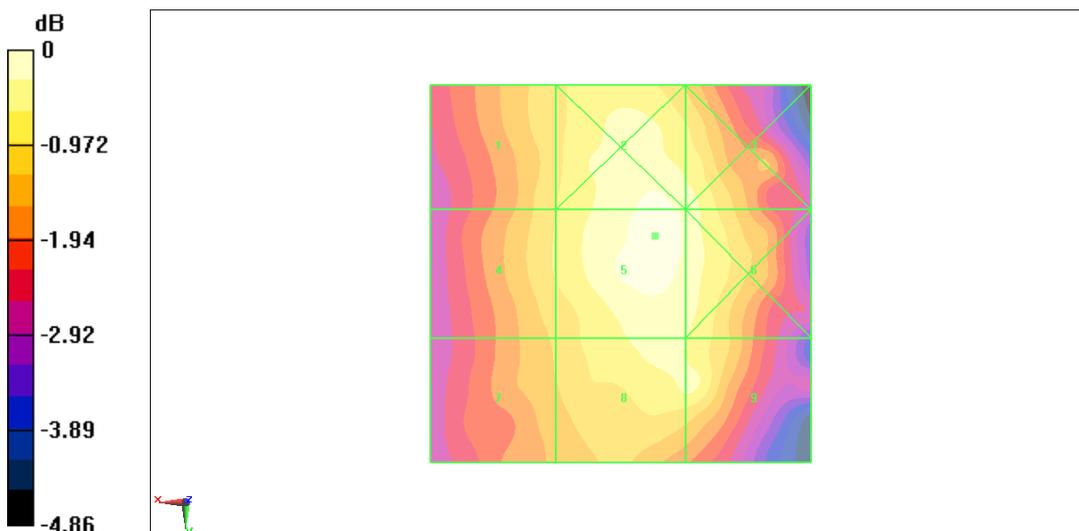
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 31.1 V/m; Power Drift = -0.026 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
66.1 M4	72.2 M4	70.2 M4
Grid 4	Grid 5	Grid 6
66.5 M4	73.9 M4	70.7 M4
Grid 7	Grid 8	Grid 9
64.2 M4	69.7 M4	69.7 M4



0 dB = 73.9V/m

Fig B.12 HAC RF E-Field CDMA 835 Low

HAC RF E-Field CDMA 1900 High – SO3

Date/Time: 4/12/2011 9:30:11 AM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 23.3°C Liquid Temperature: 22.5°C

Communication System: CDMA 1900; Frequency: 1908.75 MHz; Duty Cycle: 1:1

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1)

E Scan - ER3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 46.2 V/m

Probe Modulation Factor = 2.91

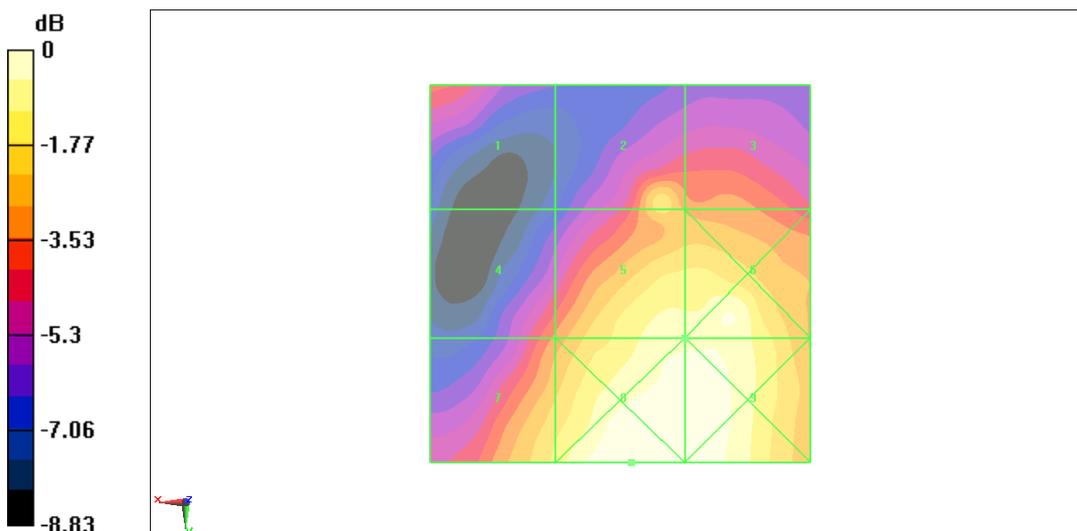
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 15.9 V/m; Power Drift = -0.097 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 32.3 M4	Grid 2 40 M4	Grid 3 35.5 M4
Grid 4 34.2 M4	Grid 5 46.2 M4	Grid 6 47.3 M4
Grid 7 41.9 M4	Grid 8 50.3 M4	Grid 9 49.7 M4



0 dB = 50.3V/m

Fig B.13 HAC RF E-Field CDMA 1900 High

HAC RF E-Field CDMA 1900 Middle – SO3

Date/Time: 4/12/2011 9:11:01 AM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 23.3°C Liquid Temperature: 22.5°C

Communication System: CDMA 1900; Frequency: 1880 MHz; Duty Cycle: 1:1

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1)

E Scan - ER3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 62.6 V/m

Probe Modulation Factor = 2.89

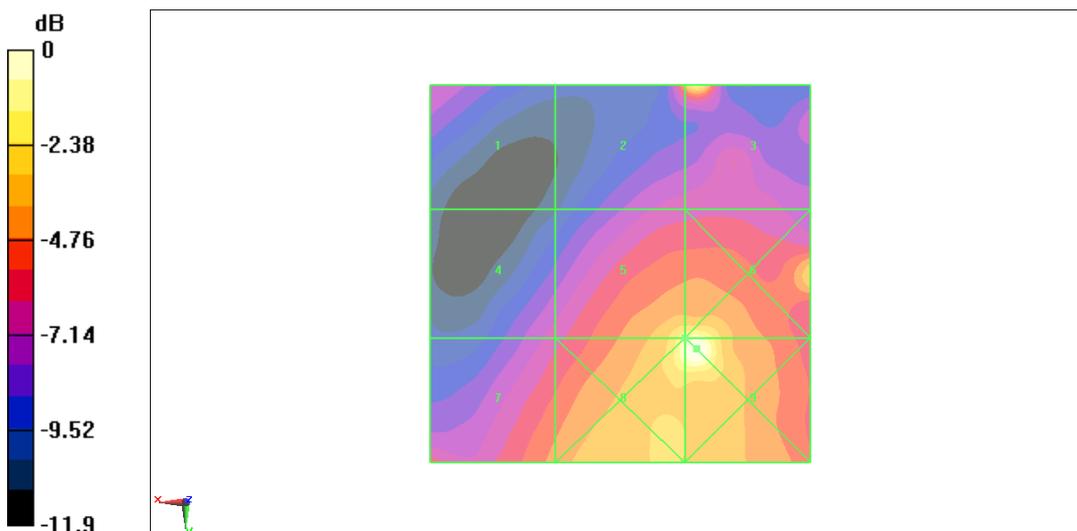
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 16.5 V/m; Power Drift = -0.178 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 33.6 M4	Grid 2 49.5 M4	Grid 3 61.7 M4
Grid 4 35 M4	Grid 5 62.6 M4	Grid 6 66.9 M3
Grid 7 45.3 M4	Grid 8 68.9 M3	Grid 9 75.3 M3



0 dB = 75.3V/m

Fig B.14 HAC RF E-Field CDMA 1900 Middle

HAC RF E-Field CDMA 1900 Low – SO3

Date/Time: 4/12/2011 9:17:16 AM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 23.3°C Liquid Temperature: 22.5°C

Communication System: CDMA 1900; Frequency: 1851.25 MHz; Duty Cycle: 1:1

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1)

E Scan - ER3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 50.7 V/m

Probe Modulation Factor = 2.92

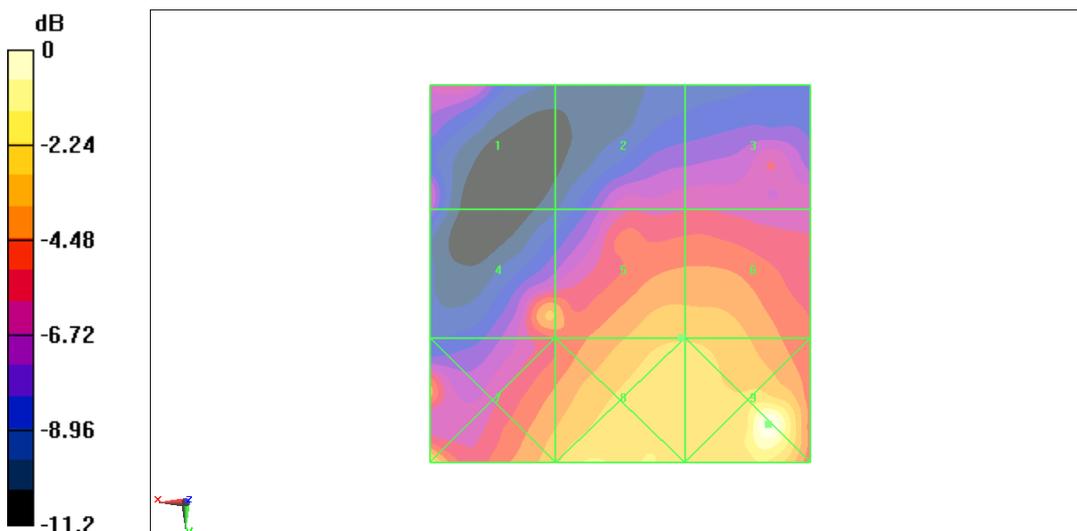
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 16.8 V/m; Power Drift = 0.051 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 37 M4	Grid 2 36.2 M4	Grid 3 36.5 M4
Grid 4 47.6 M4	Grid 5 50.7 M4	Grid 6 50.6 M4
Grid 7 57.9 M4	Grid 8 56.4 M4	Grid 9 71.9 M3



0 dB = 71.9V/m

Fig B.15 HAC RF E-Field CDMA 1900 Low

HAC RF H-Field CDMA 1700 High

Date/Time: 4/12/2011 3:49:18 PM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 23.3°C Liquid Temperature: 22.5°C

Communication System: CDMA 1700; Frequency: 1753.75 MHz; Duty Cycle: 1:1

Probe: H3DV6 - SN6260;

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.117 A/m

Probe Modulation Factor = 1

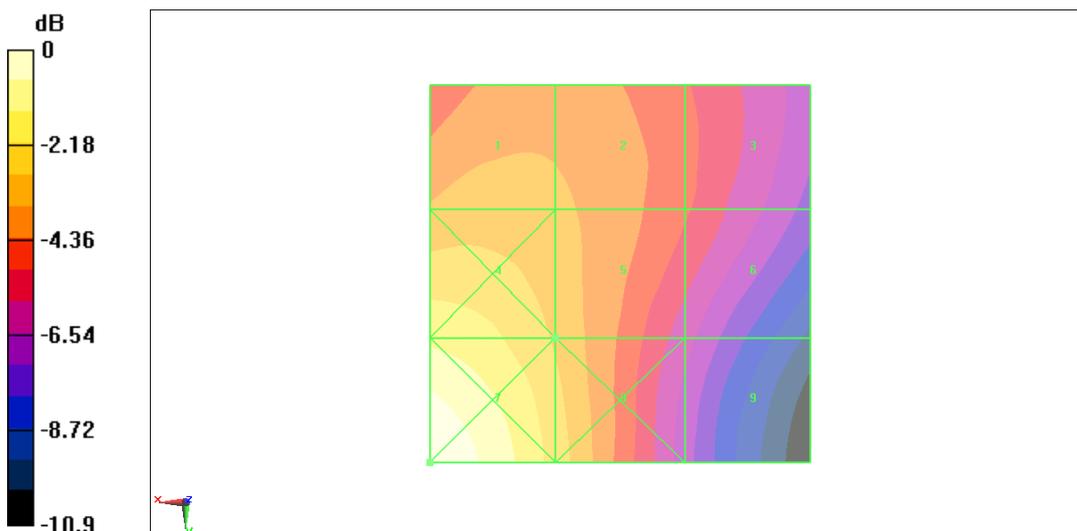
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.109 A/m; Power Drift = 0.074 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.114 M4	Grid 2 0.111 M4	Grid 3 0.094 M4
Grid 4 0.137 M4	Grid 5 0.117 M4	Grid 6 0.093 M4
Grid 7 0.165 M4	Grid 8 0.124 M4	Grid 9 0.081 M4



0 dB = 0.165A/m

Fig B.16 HAC RF H-Field CDMA 1700 High

HAC RF H-Field CDMA 1700 Middle

Date/Time: 4/12/2011 4:09:32 PM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 23.3°C Liquid Temperature: 22.5°C

Communication System: CDMA 1700; Frequency: 1732.5 MHz; Duty Cycle: 1:1

Probe: H3DV6 - SN6260;

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.112 A/m

Probe Modulation Factor = 1

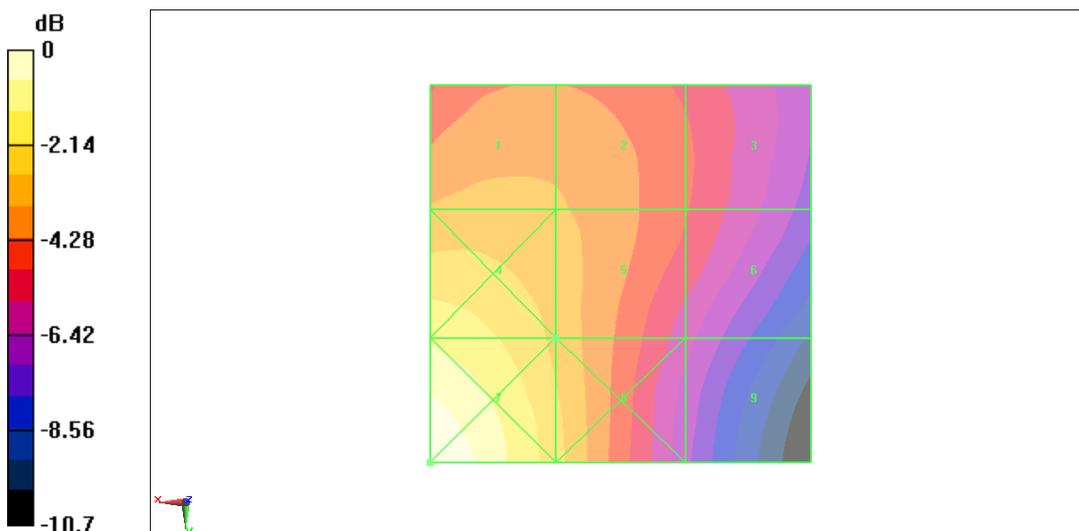
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.108 A/m; Power Drift = -0.021 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.109 M4	Grid 2 0.107 M4	Grid 3 0.091 M4
Grid 4 0.133 M4	Grid 5 0.112 M4	Grid 6 0.090 M4
Grid 7 0.159 M4	Grid 8 0.118 M4	Grid 9 0.079 M4



0 dB = 0.159A/m

Fig B.17 HAC RF H-Field CDMA 1700 Middle

HAC RF H-Field CDMA 1700 Low

Date/Time: 4/12/2011 4:03:47 PM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 23.3°C Liquid Temperature: 22.5°C

Communication System: CDMA 1700; Frequency: 1711.25 MHz; Duty Cycle: 1:1

Probe: H3DV6 - SN6260;

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.111 A/m

Probe Modulation Factor = 1

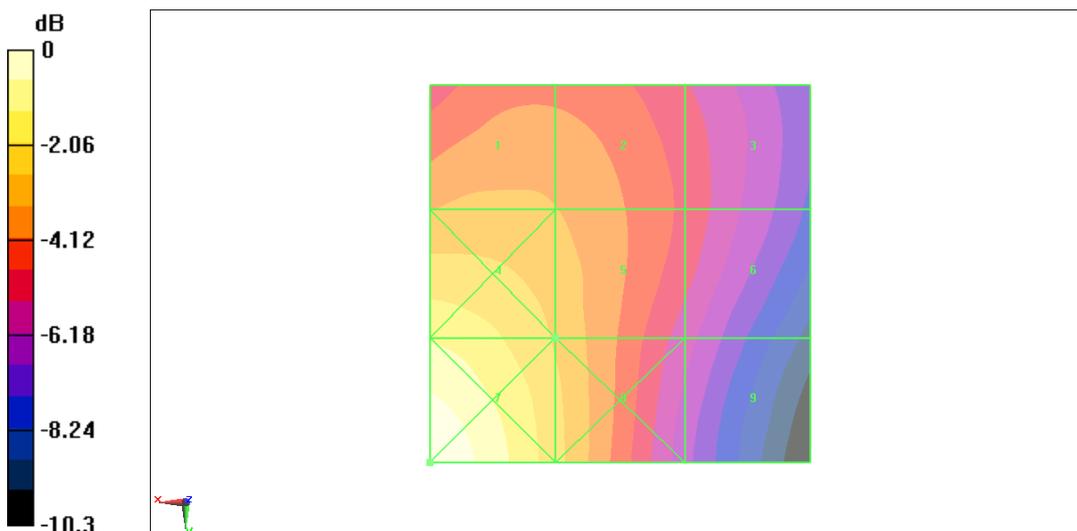
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.105 A/m; Power Drift = 0.00907 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.106 M4	Grid 2 0.104 M4	Grid 3 0.087 M4
Grid 4 0.131 M4	Grid 5 0.111 M4	Grid 6 0.087 M4
Grid 7 0.154 M4	Grid 8 0.116 M4	Grid 9 0.079 M4



0 dB = 0.154A/m

Fig B.18 HAC RF H-Field CDMA 1700 Low

HAC RF H-Field CDMA 835 High – SO55

Date/Time: 4/12/2011 2:38:53 PM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 23.3°C Liquid Temperature: 22.5°C

Communication System: CDMA 835; Frequency: 848.31 MHz; Duty Cycle: 1:1

Probe: H3DV6 - SN6260;

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.106 A/m

Probe Modulation Factor = 0.909

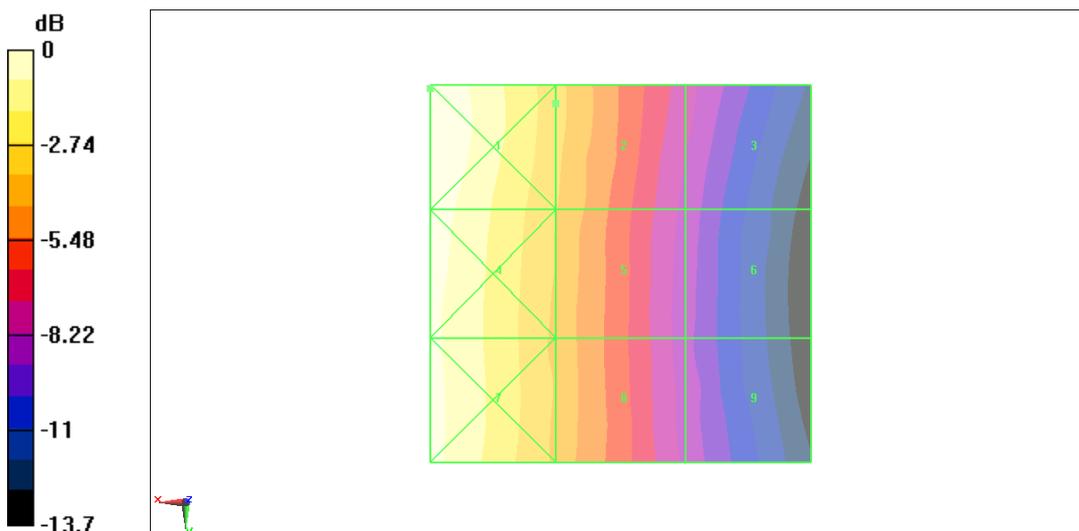
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.085 A/m; Power Drift = 0.064 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.155 M4	Grid 2 0.106 M4	Grid 3 0.063 M4
Grid 4 0.147 M4	Grid 5 0.102 M4	Grid 6 0.058 M4
Grid 7 0.144 M4	Grid 8 0.101 M4	Grid 9 0.059 M4



0 dB = 0.155A/m

Fig B.19 HAC RF H-Field CDMA 835 High

HAC RF H-Field CDMA 835 Middle – SO55

Date/Time: 4/12/2011 2:44:27 PM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 23.3°C Liquid Temperature: 22.5°C

Communication System: CDMA 835; Frequency: 836.52 MHz; Duty Cycle: 1:1

Probe: H3DV6 - SN6260;

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.104 A/m

Probe Modulation Factor = 0.891

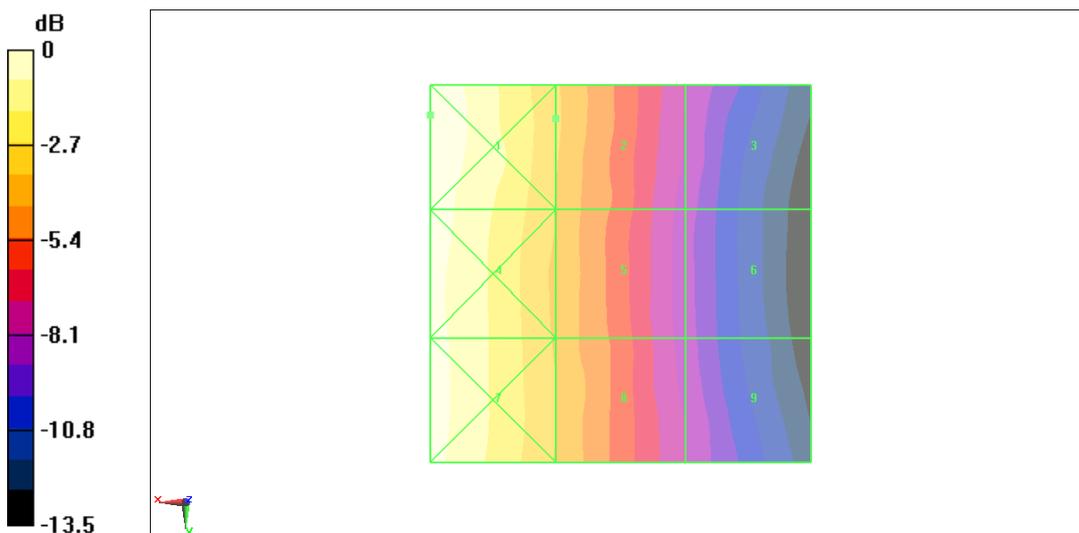
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.087 A/m; Power Drift = -0.037 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.154 M4	Grid 2 0.104 M4	Grid 3 0.061 M4
Grid 4 0.147 M4	Grid 5 0.101 M4	Grid 6 0.058 M4
Grid 7 0.145 M4	Grid 8 0.102 M4	Grid 9 0.061 M4



0 dB = 0.154A/m

Fig B.20 HAC RF H-Field CDMA 835 Middle

HAC RF H-Field CDMA 835 Low – SO55

Date/Time: 4/12/2011 2:50:02 PM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 23.3°C Liquid Temperature: 22.5°C

Communication System: CDMA 835; Frequency: 824.7 MHz; Duty Cycle: 1:1

Probe: H3DV6 - SN6260;

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.099 A/m

Probe Modulation Factor = 0.896

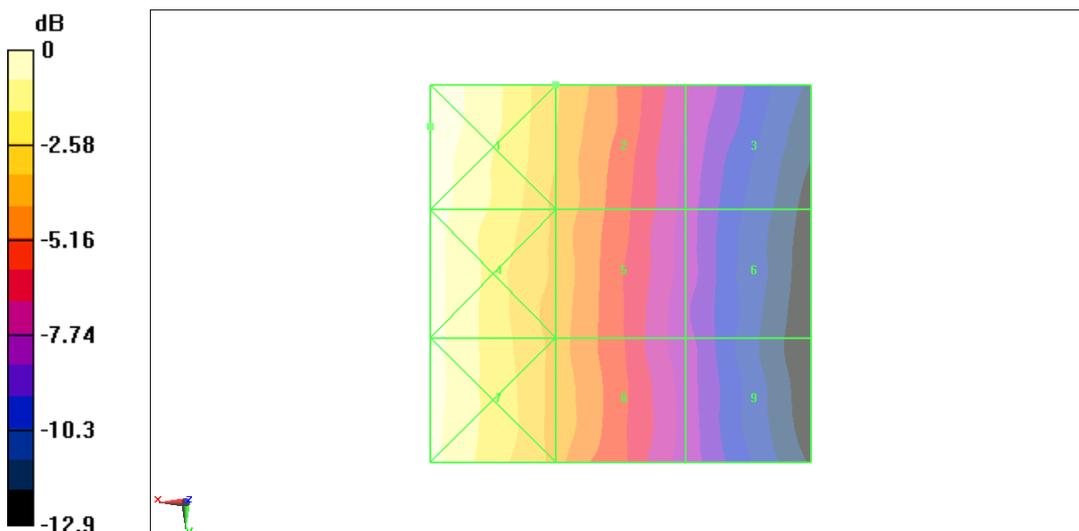
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.085 A/m; Power Drift = -0.113 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.145 M4	Grid 2 0.099 M4	Grid 3 0.061 M4
Grid 4 0.140 M4	Grid 5 0.095 M4	Grid 6 0.057 M4
Grid 7 0.139 M4	Grid 8 0.094 M4	Grid 9 0.057 M4



0 dB = 0.145A/m

Fig B.21 HAC RF H-Field CDMA 835 Low

HAC RF H-Field CDMA 1900 High – SO55

Date/Time: 4/12/2011 3:06:49 PM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 23.3°C Liquid Temperature: 22.5°C

Communication System: CDMA 1900; Frequency: 1908.75 MHz; Duty Cycle: 1:1

Probe: H3DV6 - SN6260;

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.115 A/m

Probe Modulation Factor = 0.965

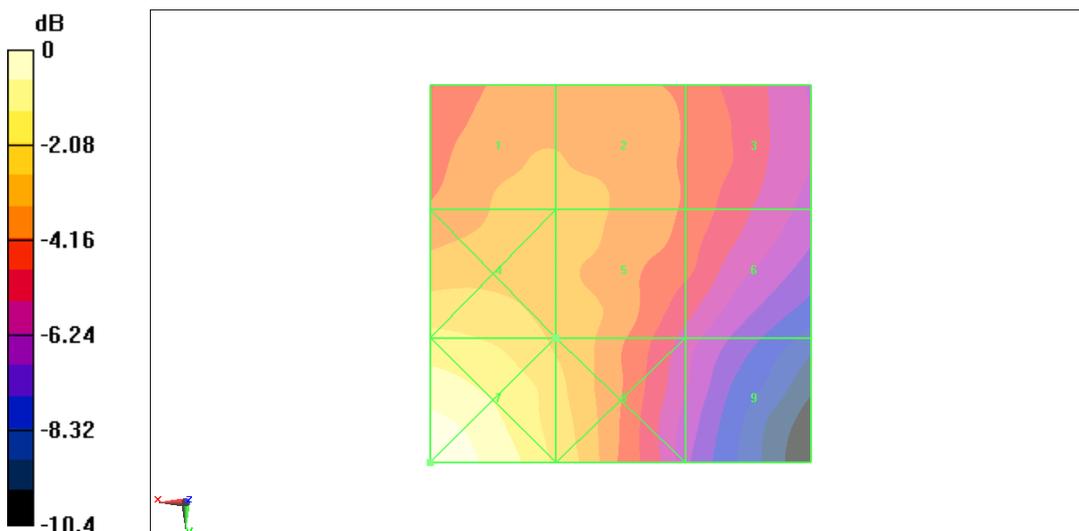
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.113 A/m; Power Drift = -0.047 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.110 M4	Grid 2 0.110 M4	Grid 3 0.099 M4
Grid 4 0.129 M4	Grid 5 0.115 M4	Grid 6 0.098 M4
Grid 7 0.160 M4	Grid 8 0.124 M4	Grid 9 0.082 M4



0 dB = 0.160A/m

Fig B.22 HAC RF H-Field CDMA 1900 High

HAC RF H-Field CDMA 1900 Middle – SO55

Date/Time: 4/12/2011 3:12:24 PM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 23.3°C Liquid Temperature: 22.5°C

Communication System: CDMA 1900; Frequency: 1880 MHz; Duty Cycle: 1:1

Probe: H3DV6 - SN6260;

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.108 A/m

Probe Modulation Factor = 0.920

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.112 A/m; Power Drift = -0.030 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.102 M4	Grid 2 0.102 M4	Grid 3 0.092 M4
Grid 4 0.123 M4	Grid 5 0.108 M4	Grid 6 0.090 M4
Grid 7 0.150 M4	Grid 8 0.115 M4	Grid 9 0.077 M4



0 dB = 0.150A/m

Fig B.23 HAC RF H-Field CDMA 1900 Middle

HAC RF H-Field CDMA 1900 Low – SO55

Date/Time: 4/12/2011 3:18:01 PM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 23.3°C Liquid Temperature: 22.5°C

Communication System: CDMA 1900; Frequency: 1851.25 MHz; Duty Cycle: 1:1

Probe: H3DV6 - SN6260;

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.116 A/m

Probe Modulation Factor = 0.926

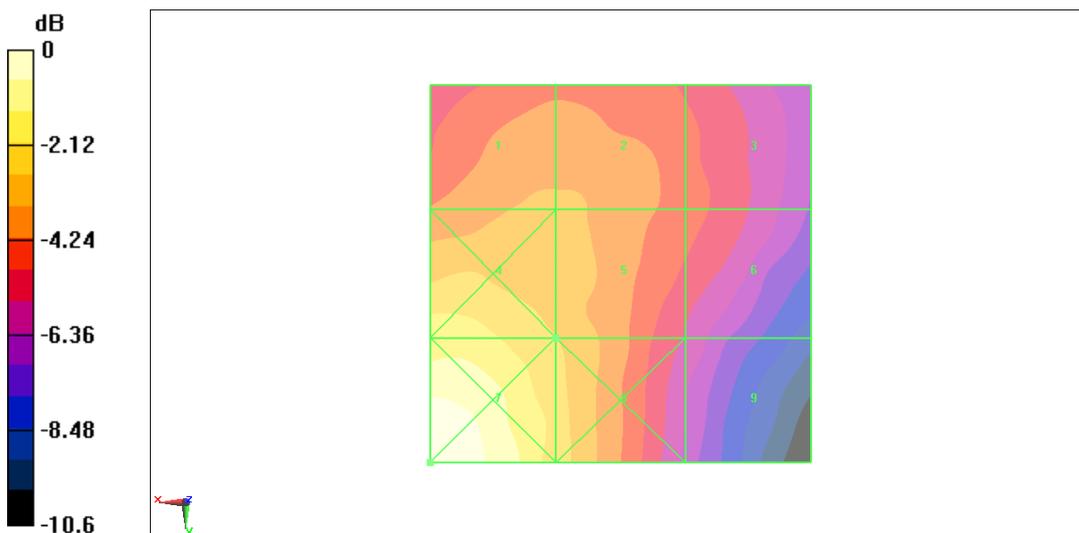
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.119 A/m; Power Drift = -0.173 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.108 M4	Grid 2 0.108 M4	Grid 3 0.095 M4
Grid 4 0.131 M4	Grid 5 0.116 M4	Grid 6 0.094 M4
Grid 7 0.160 M4	Grid 8 0.122 M4	Grid 9 0.083 M4



0 dB = 0.160A/m

Fig B.24 HAC RF H-Field CDMA 1900 Low

HAC RF H-Field CDMA 835 High – SO3

Date/Time: 4/12/2011 2:32:29 PM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 23.3°C Liquid Temperature: 22.5°C

Communication System: CDMA 835; Frequency: 848.31 MHz; Duty Cycle: 1:1

Probe: H3DV6 - SN6260;

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.165 A/m

Probe Modulation Factor = 2.86

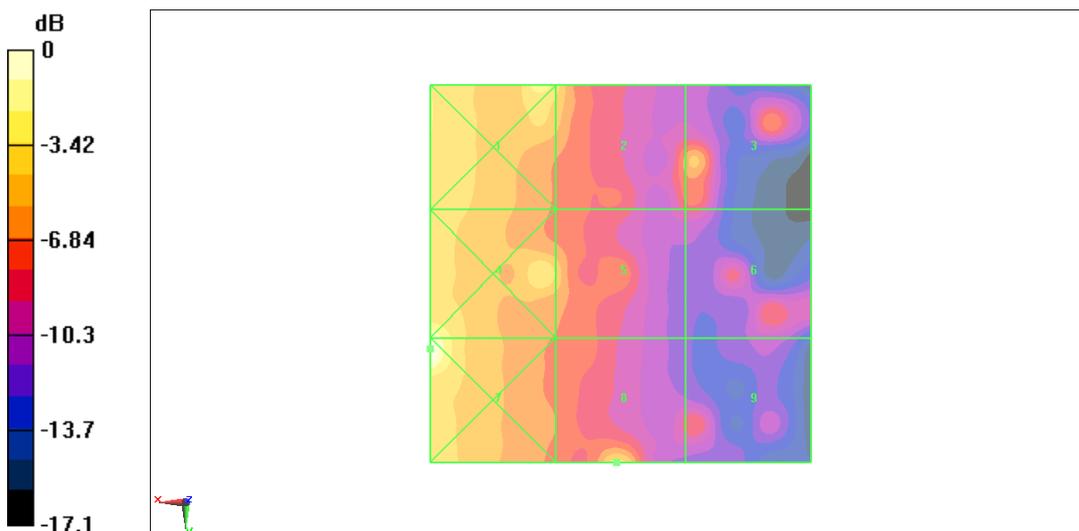
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.030 A/m; Power Drift = 0.059dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.182 M4	Grid 2 0.161 M4	Grid 3 0.138 M4
Grid 4 0.235 M4	Grid 5 0.148 M4	Grid 6 0.101 M4
Grid 7 0.255 M4	Grid 8 0.165 M4	Grid 9 0.101 M4



0 dB = 0.255A/m

Fig B.25 HAC RF H-Field CDMA 835 High

HAC RF H-Field CDMA 835 Middle – SO3

Date/Time: 4/12/2011 2:26:46 PM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 23.3°C Liquid Temperature: 22.5°C

Communication System: CDMA 835; Frequency: 836.52 MHz; Duty Cycle: 1:1

Probe: H3DV6 - SN6260;

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.159 A/m

Probe Modulation Factor = 2.92

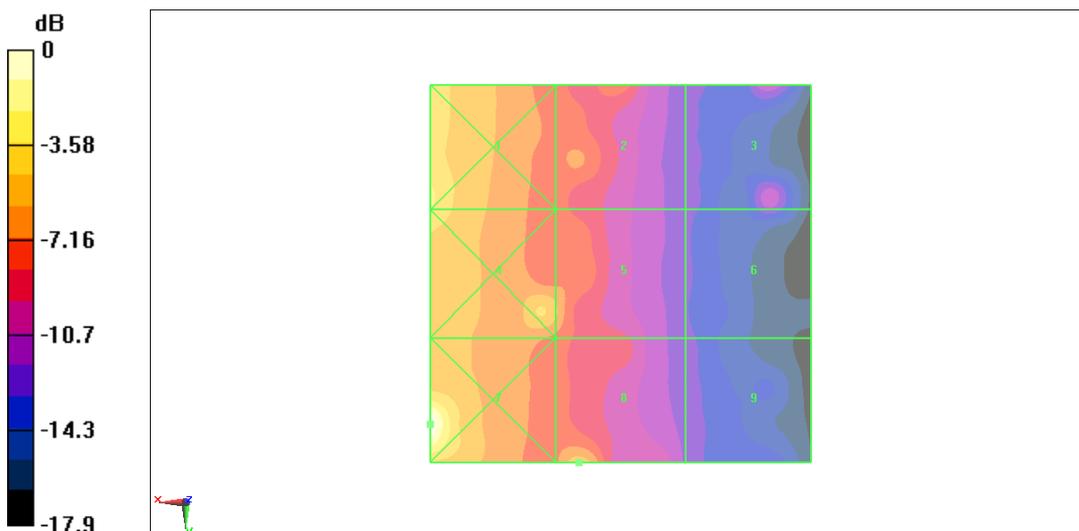
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.031 A/m; Power Drift = -0.101 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.197 M4	Grid 2 0.130 M4	Grid 3 0.082 M4
Grid 4 0.191 M4	Grid 5 0.149 M4	Grid 6 0.071 M4
Grid 7 0.288 M4	Grid 8 0.159 M4	Grid 9 0.071 M4



0 dB = 0.288A/m

Fig B.26 HAC RF H-Field CDMA 835 Middle

HAC RF H-Field CDMA 835 Low – SO3

Date/Time: 4/12/2011 2:20:53 PM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 23.3°C Liquid Temperature: 22.5°C

Communication System: CDMA 835; Frequency: 824.7 MHz; Duty Cycle: 1:1

Probe: H3DV6 - SN6260;

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.116 A/m

Probe Modulation Factor = 2.92

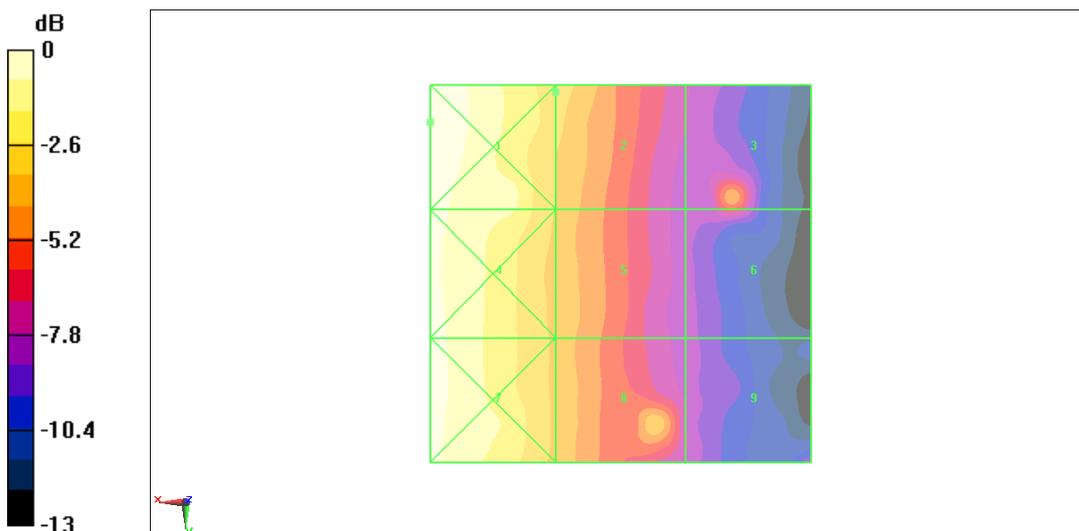
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.039 A/m; Power Drift = 0.118dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.165 M4	Grid 2 0.116 M4	Grid 3 0.098 M4
Grid 4 0.156 M4	Grid 5 0.110 M4	Grid 6 0.081 M4
Grid 7 0.157 M4	Grid 8 0.109 M4	Grid 9 0.069 M4



0 dB = 0.165A/m

Fig B.27 HAC RF H-Field CDMA 835 Low

HAC RF H-Field CDMA 1900 High – SO3

Date/Time: 4/12/2011 3:26:58 PM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 23.3°C Liquid Temperature: 22.5°C

Communication System: CDMA 1900; Frequency: 1908.75 MHz; Duty Cycle: 1:1

Probe: H3DV6 - SN6260;

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.189 A/m

Probe Modulation Factor = 2.94

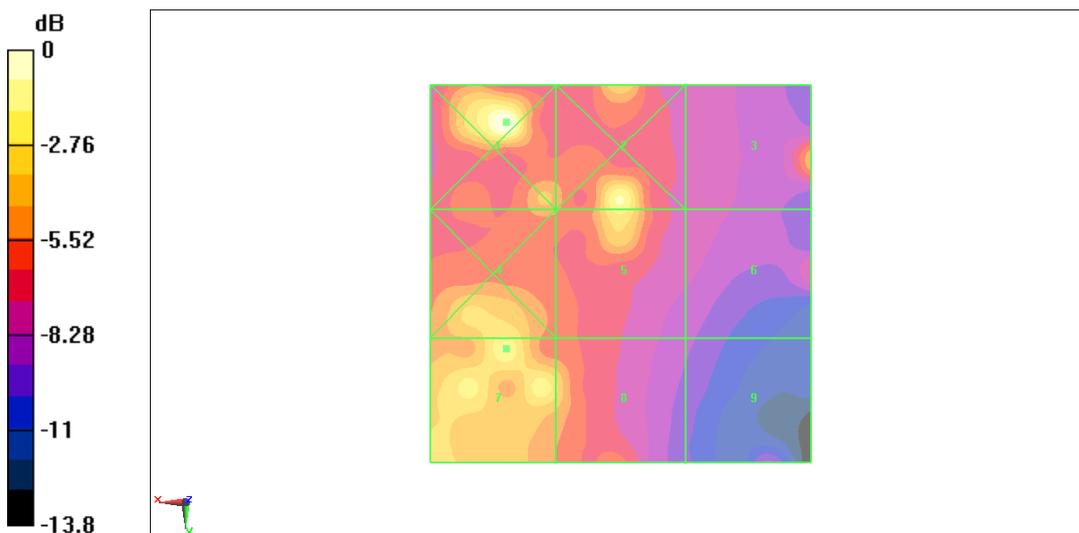
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.039 A/m; Power Drift = 0.101 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.241 M3	Grid 2 0.198 M3	Grid 3 0.145 M4
Grid 4 0.179 M4	Grid 5 0.186 M4	Grid 6 0.104 M4
Grid 7 0.189 M4	Grid 8 0.163 M4	Grid 9 0.087 M4



0 dB = 0.241A/m

Fig B.28 HAC RF H-Field CDMA 1900 High

HAC RF H-Field CDMA 1900 Middle – SO3

Date/Time: 4/12/2011 3:32:35 PM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 23.3°C Liquid Temperature: 22.5°C

Communication System: CDMA 1900; Frequency: 1880 MHz; Duty Cycle: 1:1

Probe: H3DV6 - SN6260;

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.162 A/m

Probe Modulation Factor = 2.97

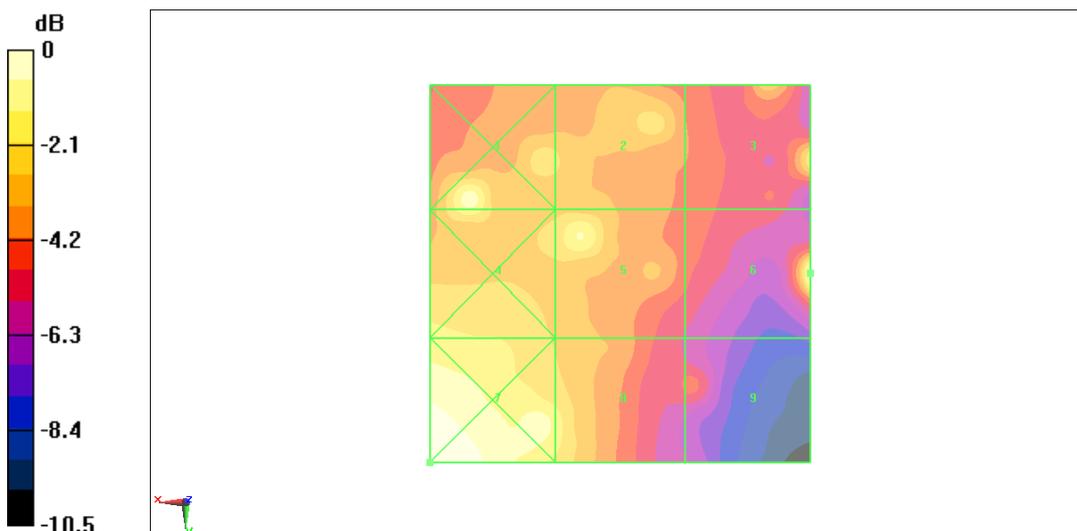
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.039 A/m; Power Drift = 0.054 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.149 M4	Grid 2 0.126 M4	Grid 3 0.130 M4
Grid 4 0.141 M4	Grid 5 0.144 M4	Grid 6 0.162 M4
Grid 7 0.168 M4	Grid 8 0.139 M4	Grid 9 0.099 M4



0 dB = 0.168A/m

Fig B.29 HAC RF H-Field CDMA 1900 Middle

HAC RF H-Field CDMA 1900 Low – SO3

Date/Time: 4/12/2011 3:38:15 PM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 23.3°C Liquid Temperature: 22.5°C

Communication System: CDMA 1900; Frequency: 1851.25 MHz; Duty Cycle: 1:1

Probe: H3DV6 - SN6260;

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.219 A/m

Probe Modulation Factor = 2.97

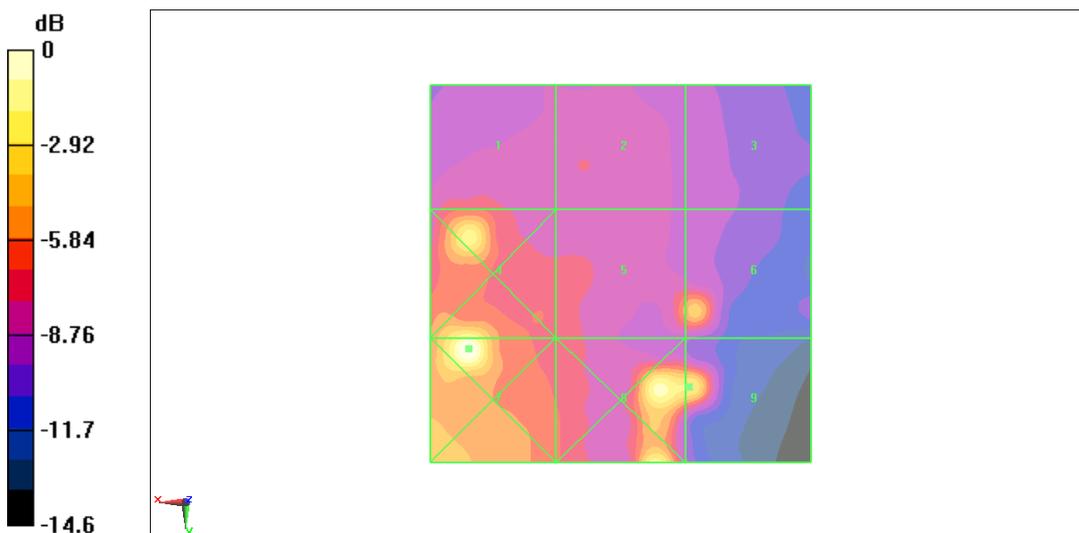
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.042 A/m; Power Drift = 0.022 dB

Hearing Aid Near-Field Category: M3 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.137 M4	Grid 2 0.123 M4	Grid 3 0.107 M4
Grid 4 0.245 M3	Grid 5 0.163 M4	Grid 6 0.182 M4
Grid 7 0.299 M3	Grid 8 0.251 M3	Grid 9 0.219 M3



0 dB = 0.299A/m

Fig B.30 HAC RF H-Field CDMA 1900 Low

Total M-rating of CDMA 1700 MHz Band

Date/Time: 4/12/2011 10:06:03 AM, Date/Time: 4/12/2011 3:49:18 PM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³ Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature:23.3°C Liquid Temperature: 22.5°C

Communication System: CDMA 1700; Frequency: 1753.75 MHz; Duty Cycle: 1:1

Probe: ER3DV6 - SN2428Probe: H3DV6 - SN6260;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 47.5 V/m

Probe Modulation Factor = 1

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 48.7 V/m; Power Drift = 0.047 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
25.7 M4	35.3 M4	35.5 M4
Grid 4	Grid 5	Grid 6
36.6 M4	47.5 M4	47.5 M4
Grid 7	Grid 8	Grid 9
46.1 M4	51 M4	50.4 M4

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.117 A/m

Probe Modulation Factor = 1

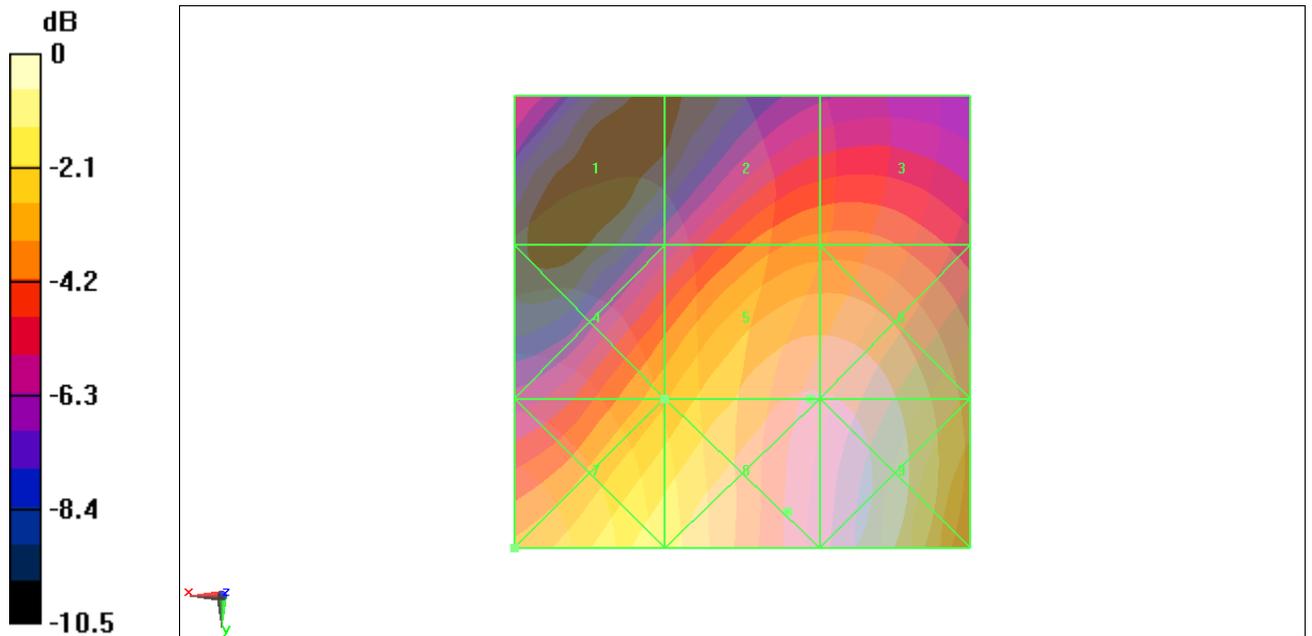
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.109 A/m; Power Drift = 0.074 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.114 M4	0.111 M4	0.094 M4
Grid 4	Grid 5	Grid 6
0.137 M4	0.117 M4	0.093 M4
Grid 7	Grid 8	Grid 9
0.165 M4	0.124 M4	0.081 M4



0 dB = 51V/m

RF RESULTS AND M-RATING	E-Field M Rating	M4 (AWF 0 dB)
	H-Field M Rating	M4 (AWF 0 dB)
	Total M Rating	M4

Fig B.31 Total M-rating of CDMA 1700

Total M-rating of CDMA 835 MHz Band – SO55

Date/Time: 4/12/2011 4:46:34 PM, Date/Time: 4/12/2011 2:38:53 PM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³ Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature:23.3°C Liquid Temperature: 22.5°C

Communication System: CDMA 835; Frequency: 836.52 MHz; Duty Cycle: 1:1

Probe: ER3DV6 - SN2428Probe: H3DV6 - SN6260;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 73.1 V/m

Probe Modulation Factor = 0.939

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 100.4 V/m; Power Drift = 0.020 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 67.1 M4	Grid 2 71.7 M4	Grid 3 70.2 M4
Grid 4 68 M4	Grid 5 73.1 M4	Grid 6 71 M4
Grid 7 65.2 M4	Grid 8 69.8 M4	Grid 9 67.7 M4

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.106 A/m

Probe Modulation Factor = 0.909

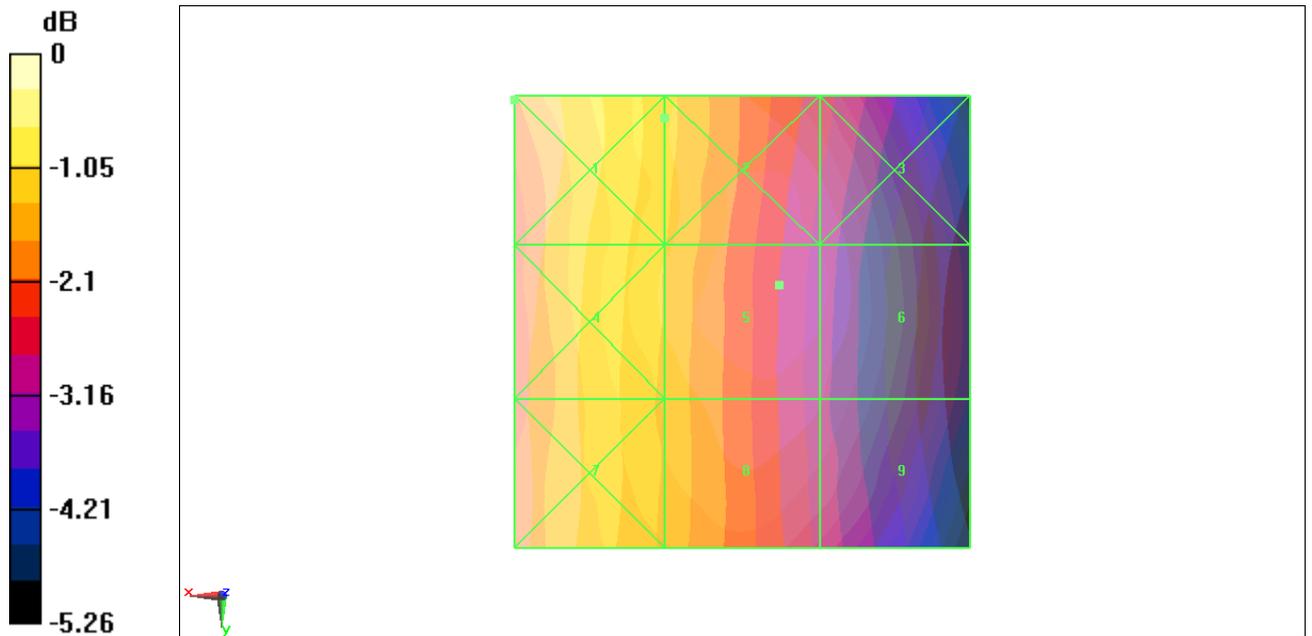
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.085 A/m; Power Drift = 0.064 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.155 M4	Grid 2 0.106 M4	Grid 3 0.063 M4
Grid 4 0.147 M4	Grid 5 0.102 M4	Grid 6 0.058 M4
Grid 7 0.144 M4	Grid 8 0.101 M4	Grid 9 0.059 M4



0 dB = 73.1V/m

RF RESULTS AND M-RATING	E-Field M Rating	M4 (AWF 0 dB)
	H-Field M Rating	M4 (AWF 0 dB)
	Total M Rating	M4

Fig B.32 Total M-rating of CDMA 835

Total M-rating of CDMA 1900 MHz Band – SO55

Date/Time: 4/12/2011 9:59:48 AM, Date/Time: 4/12/2011 3:18:01 PM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³ Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 23.3°C Liquid Temperature: 22.5°C

Communication System: CDMA 1900; Frequency: 1851.25 MHz; Duty Cycle: 1:1

Probe: ER3DV6 - SN2428 Probe: H3DV6 - SN6260; ConvF(1, 1, 1)

E Scan - ER3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 45.9 V/m

Probe Modulation Factor = 0.945

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 47.8 V/m; Power Drift = 0.137 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 31 M4	Grid 2 32.5 M4	Grid 3 32.6 M4
Grid 4 35.1 M4	Grid 5 45.9 M4	Grid 6 45.9 M4
Grid 7 44.8 M4	Grid 8 51 M4	Grid 9 49.7 M4

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.116 A/m

Probe Modulation Factor = 0.926

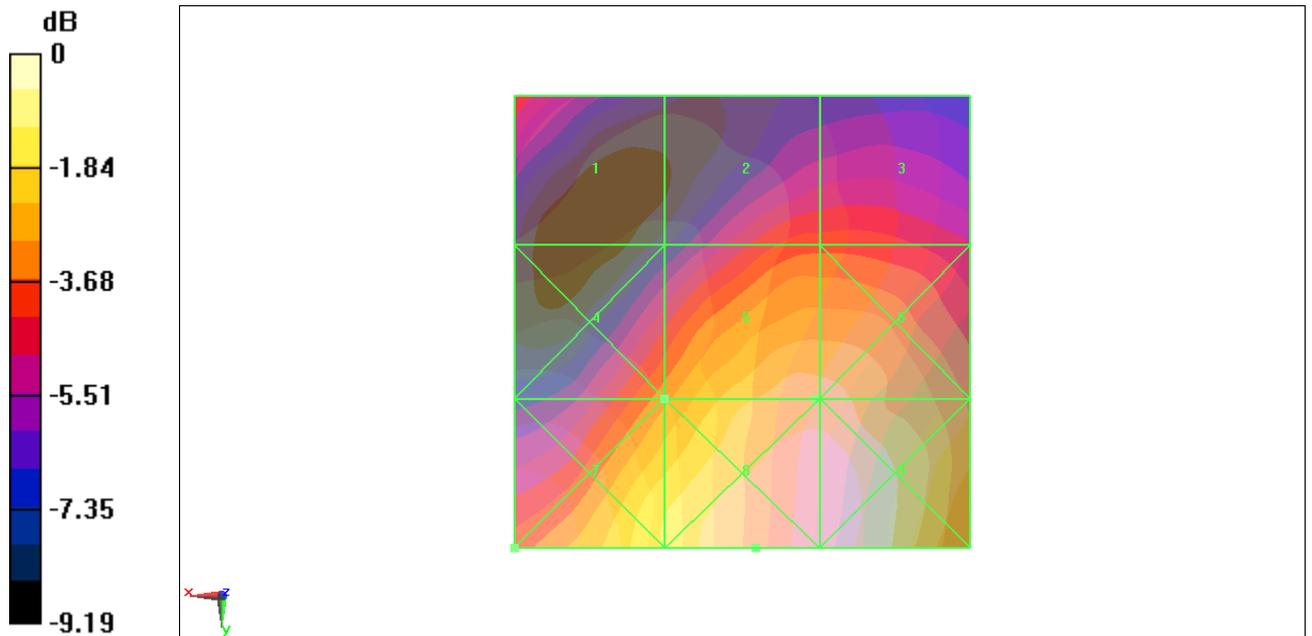
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.119 A/m; Power Drift = -0.173 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.108 M4	Grid 2 0.108 M4	Grid 3 0.095 M4
Grid 4 0.131 M4	Grid 5 0.116 M4	Grid 6 0.094 M4
Grid 7 0.160 M4	Grid 8 0.122 M4	Grid 9 0.083 M4



0 dB = 51V/m

RF RESULTS AND M-RATING	E-Field M Rating	M4 (AWF 0 dB)
	H-Field M Rating	M4 (AWF 0 dB)
	Total M Rating	M4

Fig B.33 Total M-rating of CDMA 1900

Total M-rating of CDMA 835 MHz Band – SO3

Date/Time: 4/12/2011 4:27:19 PM, Date/Time: 4/12/2011 2:32:29 PM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³ Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature:23.3°C Liquid Temperature: 22.5°C

Communication System: CDMA 835; Frequency: 836.52 MHz; Duty Cycle: 1:1

Probe: ER3DV6 - SN2428Probe: H3DV6 - SN6260;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 78.4 V/m

Probe Modulation Factor = 2.89

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 33.9 V/m; Power Drift = 0.006 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
93.8 M4	78.9 M4	73.9 M4
Grid 4	Grid 5	Grid 6
71.3 M4	78.4 M4	74.4 M4
Grid 7	Grid 8	Grid 9
75.9 M4	74.2 M4	72.7 M4

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.165 A/m

Probe Modulation Factor = 2.86

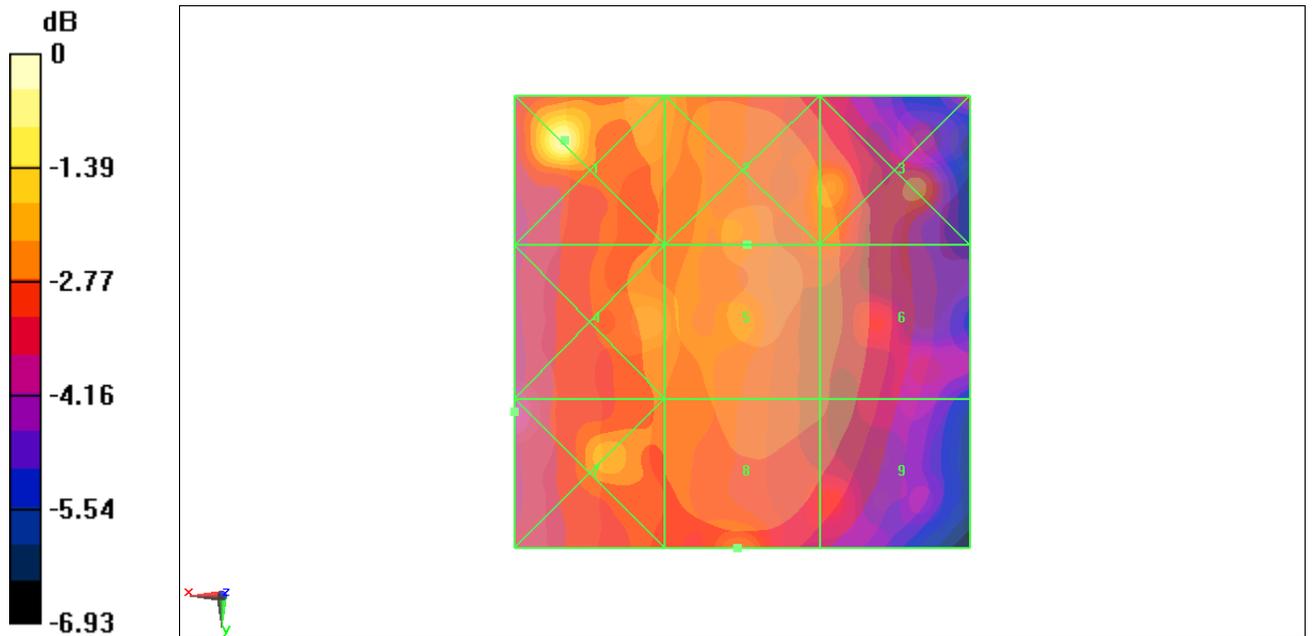
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.030 A/m; Power Drift = 0.059dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.182 M4	0.161 M4	0.138 M4
Grid 4	Grid 5	Grid 6
0.235 M4	0.148 M4	0.101 M4
Grid 7	Grid 8	Grid 9
0.255 M4	0.165 M4	0.101 M4



0 dB = 93.8V/m

RF RESULTS AND M-RATING	E-Field M Rating	M4 (AWF 0 dB)
	H-Field M Rating	M4 (AWF 0 dB)
	Total M Rating	M4

Fig B.34 Total M-rating of CDMA 835

Total M-rating of CDMA 1900 MHz Band – SO3

Date/Time: 4/12/2011 9:11:01 AM, Date/Time: 4/12/2011 3:38:15 PM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³ Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature:23.3°C Liquid Temperature: 22.5°C

Communication System: CDMA 1900; Frequency: 1851.25 MHz; Duty Cycle: 1:1

Probe: ER3DV6 - SN2428Probe: H3DV6 - SN6260;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 62.6 V/m

Probe Modulation Factor = 2.89

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 16.5 V/m; Power Drift = -0.178 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
33.6 M4	49.5 M4	61.7 M4
Grid 4	Grid 5	Grid 6
35 M4	62.6 M4	66.9 M3
Grid 7	Grid 8	Grid 9
45.3 M4	68.9 M3	75.3 M3

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.219 A/m

Probe Modulation Factor = 2.97

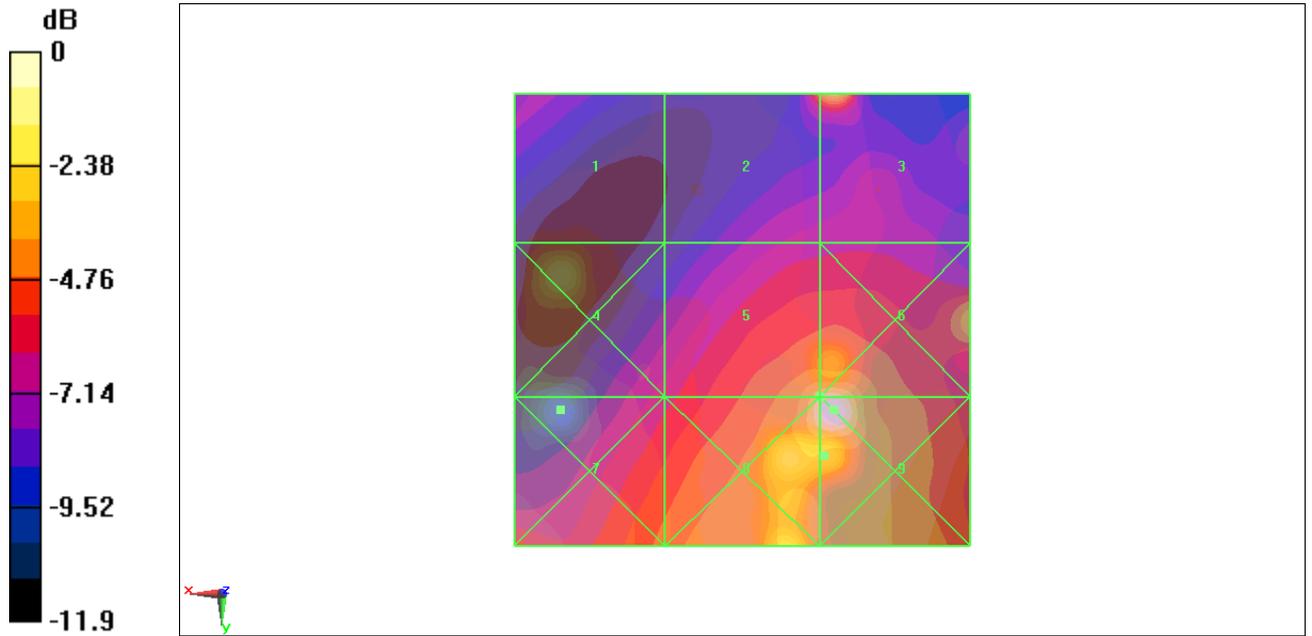
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.042 A/m; Power Drift = 0.022 dB

Hearing Aid Near-Field Category: M3 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.137 M4	0.123 M4	0.107 M4
Grid 4	Grid 5	Grid 6
0.245 M3	0.163 M4	0.182 M4
Grid 7	Grid 8	Grid 9
0.299 M3	0.251 M3	0.219 M3



0 dB = 75.3V/m

RF RESULTS AND M-RATING	E-Field M Rating	M4 (AWF 0 dB)
	H-Field M Rating	M3 (AWF 0 dB)
	Total M Rating	M3

Fig B.35 Total M-rating of CDMA 1900

ANNEX C SYSTEM VALIDATION RESULT

E SCAN of Dipole 835 MHz

Date/Time: 4/12/2011 7:42:23 AM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1

Probe: ER3DV6 - SN2428;ConvF(1, 1, 1)

E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 170.3 V/m

Probe Modulation Factor = 1

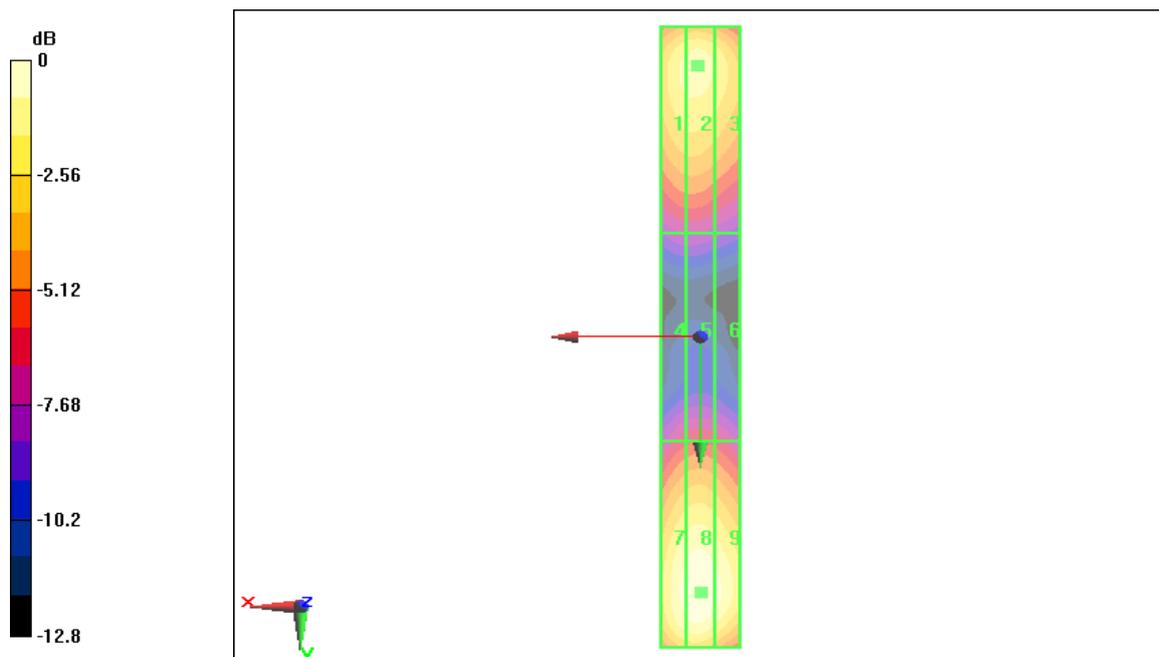
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 120.6 V/m; Power Drift = -0.063 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
145.2 M4	147.6 M4	139.9 M4
Grid 4	Grid 5	Grid 6
81.9 M4	84.3 M4	81.1 M4
Grid 7	Grid 8	Grid 9
162.0 M4	170.3 M4	162.1 M4



0 dB = 170.3V/m

H SCAN of Dipole 835 MHz

Date/Time: 4/12/2011 8:01:35 AM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1

Probe: H3DV6 - SN6260;

H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.441 A/m

Probe Modulation Factor = 1

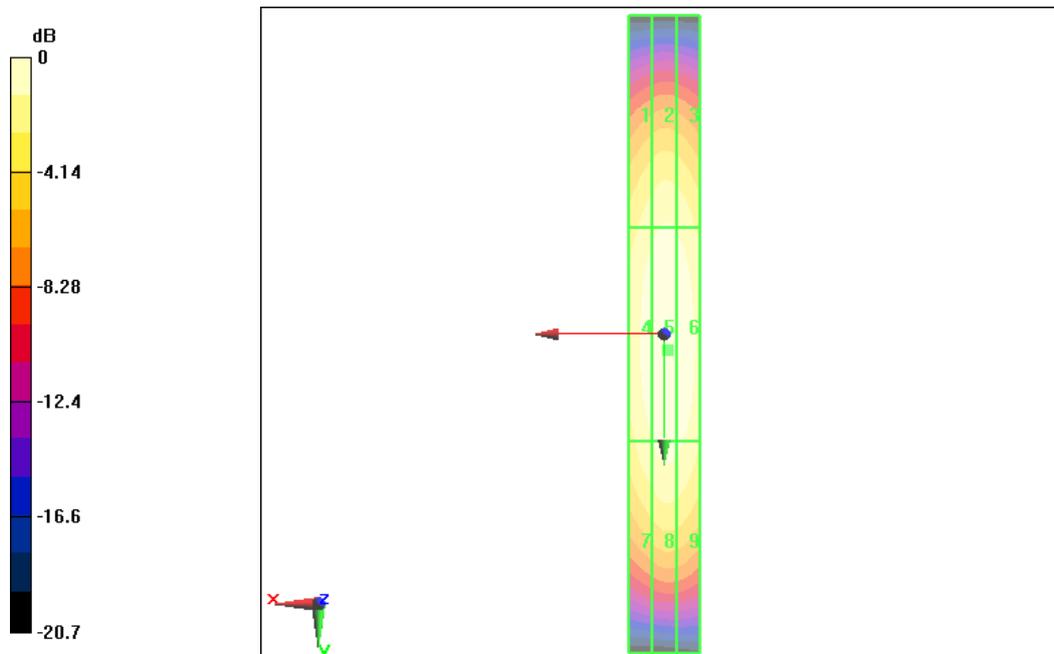
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.461 A/m; Power Drift = -0.080 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.356 M4	0.380 M4	0.367 M4
Grid 4	Grid 5	Grid 6
0.415 M4	0.441 M4	0.428 M4
Grid 7	Grid 8	Grid 9
0.367 M4	0.396 M4	0.386 M4



0 dB = 0.441A/m

E SCAN of Dipole 1880 MHz

Date/Time: 4/12/2011 8:24:25 AM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Communication System: CW; Frequency: 1900 MHz; Duty Cycle: 1:1

Probe: ER3DV6 - SN2428;ConvF(1, 1, 1)

E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 132.7 V/m

Probe Modulation Factor = 1

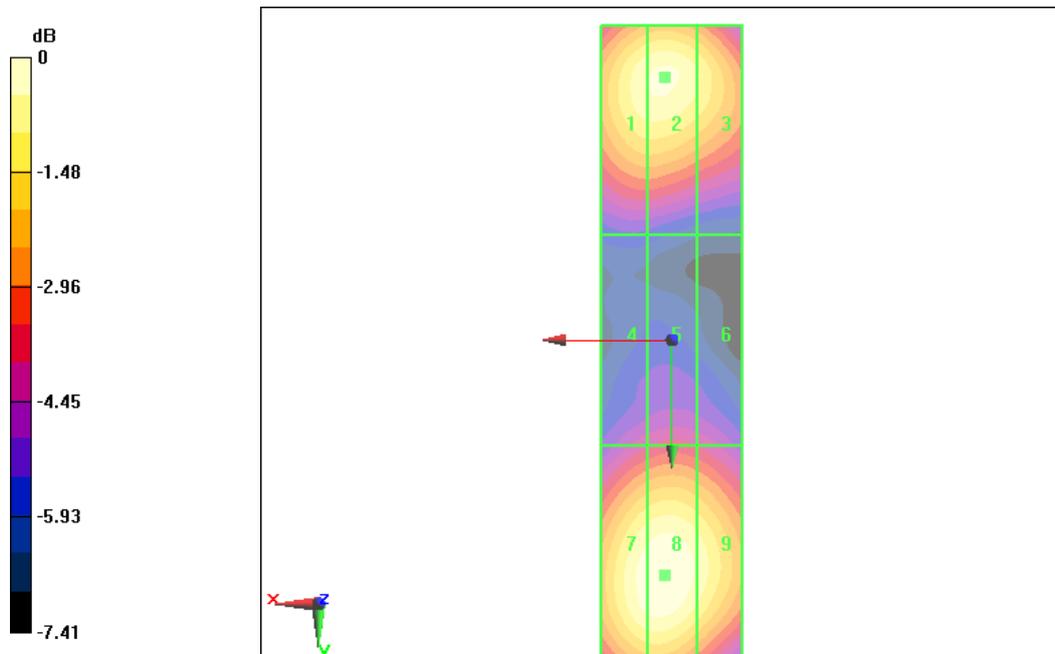
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 138.5 V/m; Power Drift = 0.089 dB

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
125.0 M2	127.1 M2	119.5 M2
Grid 4	Grid 5	Grid 6
83.2 M3	86.0 M3	83.7 M3
Grid 7	Grid 8	Grid 9
130.1 M2	132.7 M2	124.2 M2



0 dB = 132.7V/m

H SCAN of Dipole 1880 MHz

Date/Time: 4/12/2011 8:48:19 AM

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Communication System: CW; Frequency: 1900 MHz; Duty Cycle: 1:1

Probe: H3DV6 - SN6260;

H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.445 A/m

Probe Modulation Factor = 1

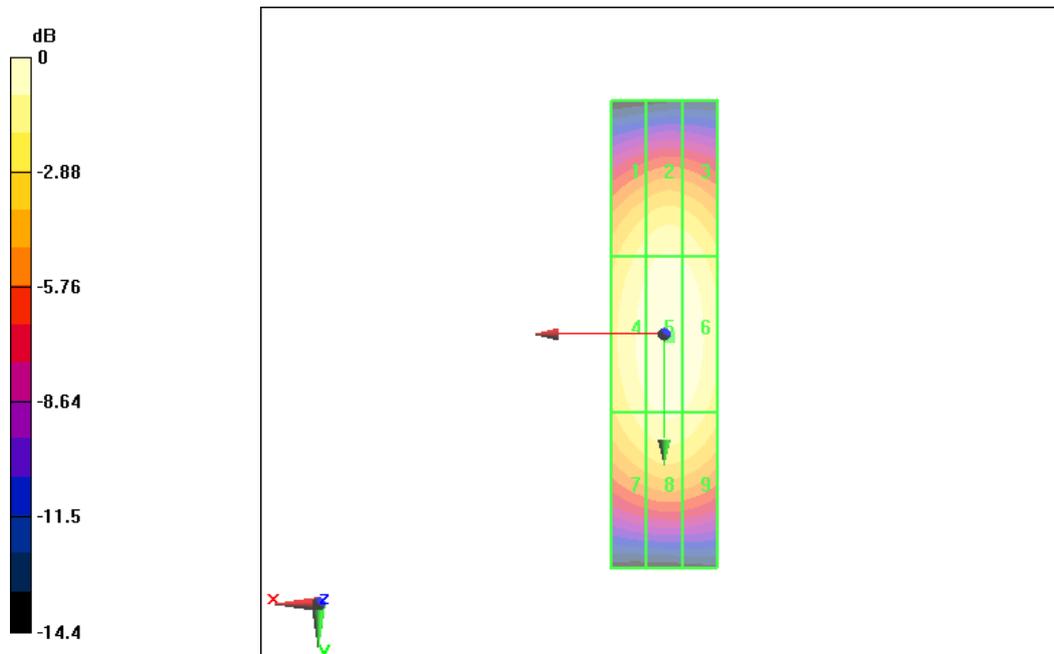
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.457 A/m; Power Drift = -0.062 dB

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.375 M2	0.396 M2	0.391 M2
Grid 4	Grid 5	Grid 6
0.412 M2	0.445 M2	0.425 M2
Grid 7	Grid 8	Grid 9
0.376 M2	0.401 M2	0.395 M2



0 dB = 0.445A/m

ANNEX D PROBE CALIBRATION CERTIFICATE

E_Probe ER3DV6

Calibration Laboratory of
Schmid & Partner
Engineering AG
Zeughausstrasse 43, 8004 Zurich, Switzerland



S Schweizerischer Kalibrierdienst
C Service suisse d'étalonnage
S Servizio svizzero di taratura
S Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 108

Client **TMC**

Certificate No: ER3-2428_Oct10

CALIBRATION CERTIFICATE

Object **ER3DV6 - SN:2428**

Calibration procedure(s) **QA CAL-02.v5 and QA CAL-25.v2
Calibration procedure for E-field probes optimized for close near field
evaluations in air**

Calibration date: **October 20, 2010**

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
Power meter E4419B	GB41293874	1-Apr-10 (No. 217-01030)	Apr-11
Power sensor E4412A	MY41495277	1-Apr-10 (No. 217-01030)	Apr-11
Power sensor E4412A	MY41498087	1-Apr-10 (No. 217-01030)	Apr-11
Reference 3 dB Attenuator	SN: S5054 (3c)	31-Mar-10 (No. 217-01026)	Mar-11
Reference 20 dB Attenuator	SN: S5086 (20b)	31-Mar-10 (No. 217-01028)	Mar-11
Reference 30 dB Attenuator	SN: S5129 (30b)	31-Mar-10 (No. 217-01027)	Mar-11
Reference Probe ER3DV6	SN: 2328	3-Oct-10 (No. ER3-2328_Oct10)	Oct-11
DAE4	SN: 789	19-Dec-09 (No. DAE4-789_Dec09)	Dec-10
Secondary Standards	ID #	Check Date (in house)	Scheduled Check
RF generator HP 8648C	US3642U01700	4-Aug-99 (in house check Oct-09)	In house check: Oct-11
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-10)	In house check: Oct-11

Calibrated by:	Name	Function	Signature
	Marcel Fehr	Laboratory Technician	

Approved by:	Name	Function	Signature
	Katja Pokovic	Technical Manager	

Issued: October 21, 2010

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

**Calibration Laboratory of
Schmid & Partner
Engineering AG**
Zeughausstrasse 43, 8004 Zurich, Switzerland



S Schweizerischer Kalibrierdienst
C Service suisse d'étalonnage
S Servizio svizzero di taratura
S Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: **SCS 108**

Glossary:

NORM _{x,y,z}	sensitivity in free space
DCP	diode compression point
CF	crest factor (1/duty_cycle) of the RF signal
A, B, C	modulation dependent linearization parameters
Polarization φ	φ rotation around probe axis
Polarization ϑ	ϑ rotation around an axis that is in the plane normal to probe axis (at measurement center), i.e., $\vartheta = 0$ is normal to probe axis
Connector Angle	information used in DASY system to align probe sensor X to the robot coordinate system

Calibration is Performed According to the Following Standards:

- a) IEEE Std 1309-2005, "IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005.

Methods Applied and Interpretation of Parameters:

- *NORM_{x,y,z}*: Assessed for E-field polarization $\vartheta = 0$ for XY sensors and $\vartheta = 90$ for Z sensor ($f \leq 900$ MHz in TEM-cell; $f > 1800$ MHz: R22 waveguide).
- *NORM(f)_{x,y,z}* = *NORM_{x,y,z}* * *frequency_response* (see Frequency Response Chart).
- *DCP_{x,y,z}*: DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- *A_{x,y,z}; B_{x,y,z}; C_{x,y,z}* are numerical linearization parameters assessed based on the data of power sweep for specific modulation signal. The parameters do not depend on frequency nor media.
- *Spherical isotropy (3D deviation from isotropy)*: in a locally homogeneous field realized using an open waveguide setup.
- *Sensor Offset*: The sensor offset corresponds to the offset of virtual measurement center from the probe tip (on probe axis). No tolerance required.
- *Connector Angle*: The angle is assessed using the information gained by determining the *NORM_x* (no uncertainty required).

ER3DV6 SN:2428

October 20, 2010

Probe ER3DV6

SN:2428

Manufactured:	September 11, 2007
Last calibrated:	October 20, 2009
Recalibrated:	October 20, 2010

Calibrated for DASYS Systems

(Note: non-compatible with DASYS2 system!)

ER3DV6 SN:2428

October 20, 2010

DASY - Parameters of Probe: ER3DV6 SN:2428

Basic Calibration Parameters

	Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm ($\mu\text{V}/(\text{V}/\text{m})^2$)	1.52	1.59	1.86	$\pm 10.1\%$
DCP (mV) [^]	91.5	93.0	98.9	

Modulation Calibration Parameters

UID	Communication System Name	PAR		A dB	B dBuV	C	VR mV	Unc (k=2)
10000	CW		X	0.00	0.00	1.00	300	$\pm 1.5\%$
			Y	0.00	0.00	1.00	300	
			Z	0.00	0.00	1.00	300	

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

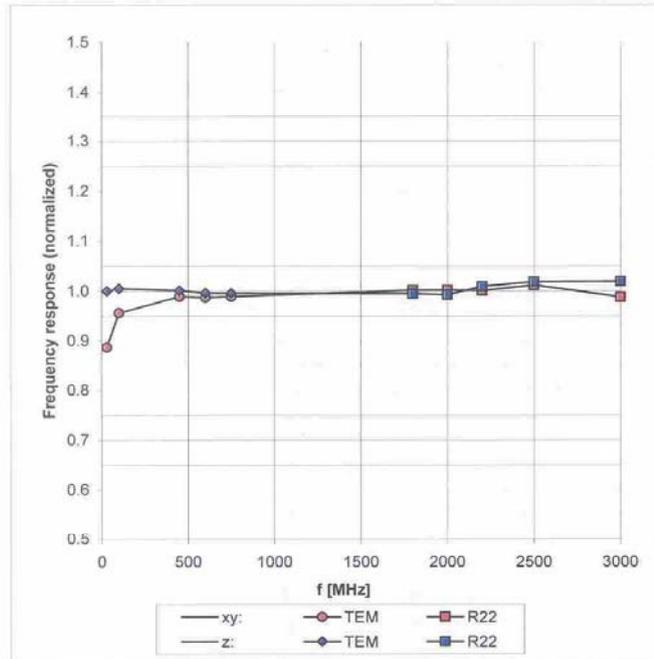
[^] numerical linearization parameter: uncertainty not required

ER3DV6 SN:2428

October 20, 2010

Frequency Response of E-Field

(TEM-Cell:ifi110 EXX, Waveguide R22)

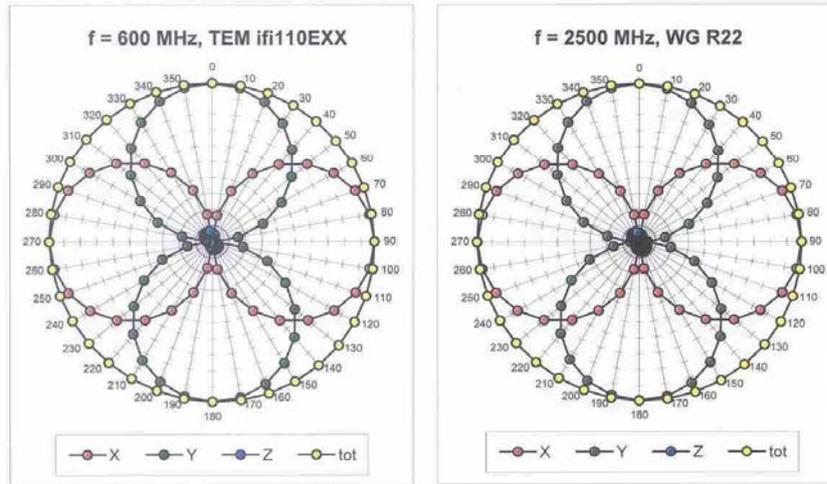


Uncertainty of Frequency Response of E-field: $\pm 6.3\%$ (k=2)

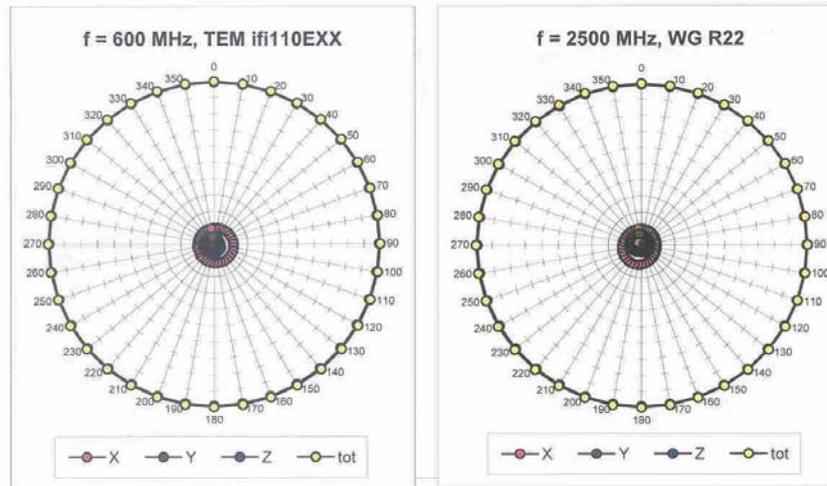
ER3DV6 SN:2428

October 20, 2010

Receiving Pattern (ϕ), $\vartheta = 0^\circ$



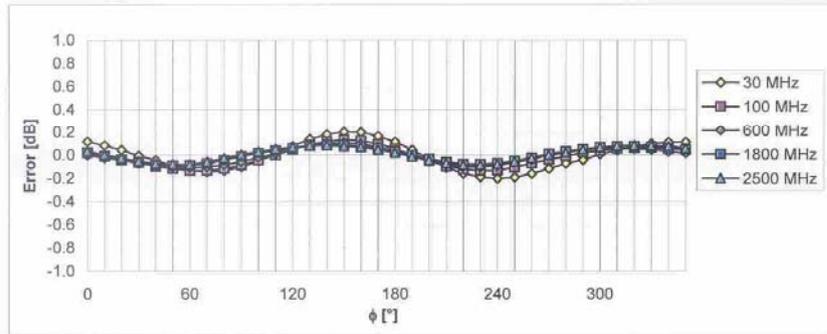
Receiving Pattern (ϕ), $\vartheta = 90^\circ$



ER3DV6 SN:2428

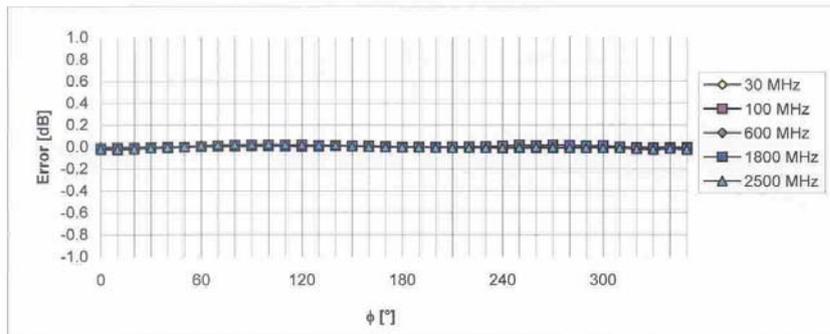
October 20, 2010

Receiving Pattern (ϕ), $\vartheta = 0^\circ$



Uncertainty of Axial Isotropy Assessment: $\pm 0.5\%$ (k=2)

Receiving Pattern (ϕ), $\vartheta = 90^\circ$

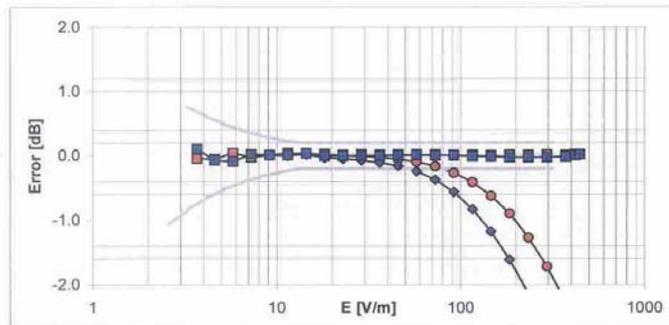
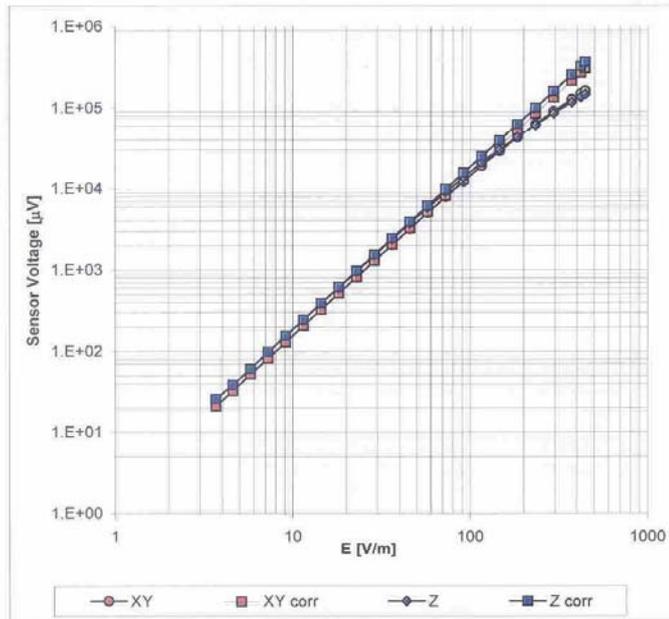


Uncertainty of Axial Isotropy Assessment: $\pm 0.5\%$ (k=2)

ER3DV6 SN:2428

October 20, 2010

Dynamic Range f(E-field) (Waveguide R22, f = 1800 MHz)

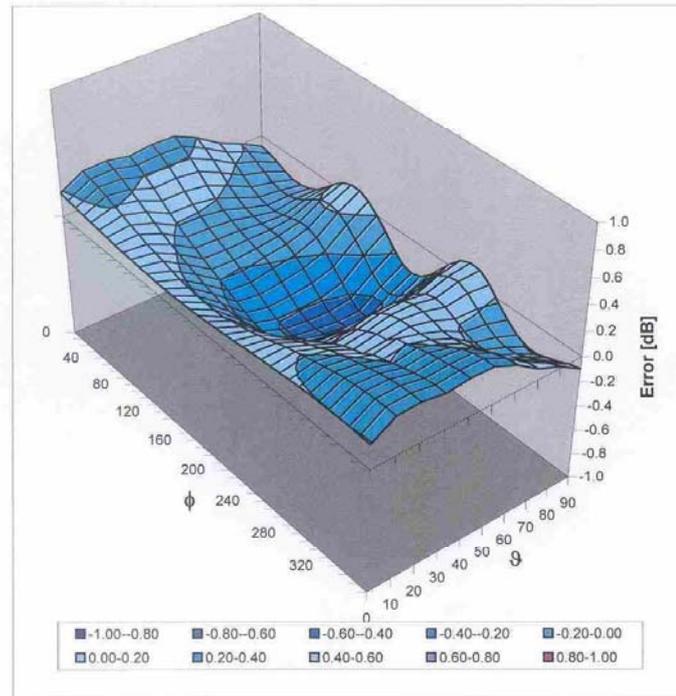


Uncertainty of Linearity Assessment: $\pm 0.6\%$ ($k=2$)

ER3DV6 SN:2428

October 20, 2010

Deviation from Isotropy in Air
Error (ϕ, ϑ), $f = 900$ MHz



Uncertainty of Spherical Isotropy Assessment: $\pm 2.6\%$ ($k=2$)

ER3DV6 SN:2428

October 20, 2010

Other Probe Parameters

Sensor Arrangement	Rectangular
Connector Angle (°)	-218.7
Mechanical Surface Detection Mode	enabled
Optical Surface Detection Mode	disabled
Probe Overall Length	337 mm
Probe Body Diameter	10 mm
Tip Length	10 mm
Tip Diameter	8.0 mm
Probe Tip to Sensor X Calibration Point	2.5 mm
Probe Tip to Sensor Y Calibration Point	2.5 mm
Probe Tip to Sensor Z Calibration Point	2.5 mm

H_Probe H3DV6

Calibration Laboratory of
Schmid & Partner
Engineering AG
Zeughausstrasse 43, 8004 Zurich, Switzerland



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Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 108

Client TMC

Certificate No: H3-6260_Oct10

CALIBRATION CERTIFICATE

Object H3DV6 - SN:6260

Calibration procedure(s) QA CAL-03.v5 and QA CAL-25.v2
Calibration procedure for H-field probes optimized for close near field evaluations in air

Calibration date: October 20, 2010

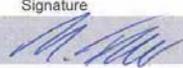
This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
Power meter E4419B	GB41293874	1-Apr-10 (No. 217-01030)	Apr-11
Power sensor E4412A	MY41495277	1-Apr-10 (No. 217-01030)	Apr-11
Power sensor E4412A	MY41498087	1-Apr-10 (No. 217-01030)	Apr-11
Reference 3 dB Attenuator	SN: S5054 (3c)	31-Mar-10 (No. 217-01026)	Mar-11
Reference 20 dB Attenuator	SN: S5086 (20b)	31-Mar-10 (No. 217-01028)	Mar-11
Reference 30 dB Attenuator	SN: S5129 (30b)	31-Mar-10 (No. 217-01027)	Mar-11
Reference Probe H3DV6	SN: 6182	3-Oct-10 (No. H3-6182_Oct10)	Oct-11
DAE4	SN: 789	19-Dec-09 (No. DAE4-789_Dec09)	Dec-10

Secondary Standards	ID #	Check Date (in house)	Scheduled Check
RF generator HP 8648C	US3642U01700	4-Aug-99 (in house check Oct-09)	In house check: Oct-11
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-10)	In house check: Oct-11

	Name	Function	Signature
Calibrated by:	Marcel Fehr	Laboratory Technician	
Approved by:	Katja Pokovic	Technical Manager	

Issued: October 21, 2010

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

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Engineering AG**
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Glossary:

NORM _{x,y,z}	sensitivity in free space
DCP	diode compression point
CF	crest factor (1/duty_cycle) of the RF signal
A, B, C	modulation dependent linearization parameters
Polarization φ	φ rotation around probe axis
Polarization ϑ	ϑ rotation around an axis that is in the plane normal to probe axis (at measurement center), i.e., $\vartheta = 0$ is normal to probe axis
Connector Angle	information used in DASY system to align probe sensor X to the robot coordinate system

Calibration is Performed According to the Following Standards:

- a) IEEE Std 1309-2005, "IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005.

Methods Applied and Interpretation of Parameters:

- *NORM_{x,y,z}*: Assessed for E-field polarization $\vartheta = 0$ for XY sensors and $\vartheta = 90$ for Z sensor ($f \leq 900$ MHz in TEM-cell; $f > 1800$ MHz: R22 waveguide).
- $X, Y, Z(f)_{a0a1a2} = X, Y, Z_{a0a1a2} * frequency_response$ (see Frequency Response Chart).
- *DCP_{x,y,z}*: DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- *A_{x,y,z}; B_{x,y,z}; C_{x,y,z}* are numerical linearization parameters assessed based on the data of power sweep for specific modulation signal. The parameters do not depend on frequency nor media.
- *Spherical isotropy (3D deviation from isotropy)*: in a locally homogeneous field realized using an open waveguide setup.
- *Sensor Offset*: The sensor offset corresponds to the offset of virtual measurement center from the probe tip (on probe axis). No tolerance required.
- *Connector Angle*: The angle is assessed using the information gained by determining the X_{a0a1a2} (no uncertainty required).

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Probe H3DV6

SN:6260

Manufactured:	September 7, 2007
Last calibrated:	October 20, 2009
Recalibrated:	October 20, 2010

Calibrated for DASY Systems

(Note: non-compatible with DASY2 system!)

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DASY - Parameters of Probe: H3DV6 SN:6260

Basic Calibration Parameters

		Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm (A/m / $\sqrt{\mu V}$)	a0	2.47E-3	2.49E-3	2.95E-3	$\pm 10.1\%$
Norm (A/m / $\sqrt{\mu V}$)	a1	-2.97E-5	5.62E-6	-4.47E-5	$\pm 10.1\%$
Norm (A/m / $\sqrt{\mu V}$)	a2	4.84E-5	4.36E-5	6.01E-5	$\pm 10.1\%$
DCP (mV) ^A		84.5	90.3	83.9	

Modulation Calibration Parameters

UID	Communication System Name	PAR		A dB	B dBuV	C	VR mV	Unc (k=2)
10000	CW	0.00	X	0.00	0.00	1.00	300	$\pm 1.5\%$
			Y	0.00	0.00	1.00	300	
			Z	0.00	0.00	1.00	300	

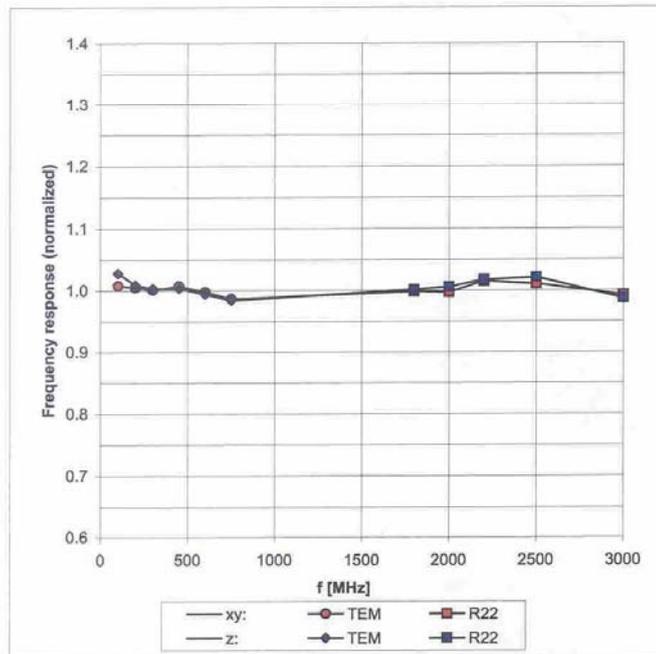
The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

¹ numerical linearization parameter: uncertainty not required

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Frequency Response of H-Field (TEM-Cell:ifi110 EXX, Waveguide R22)

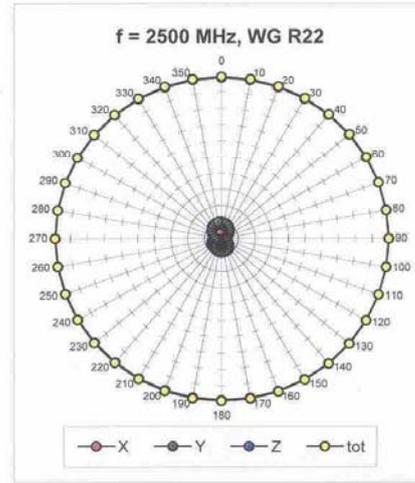
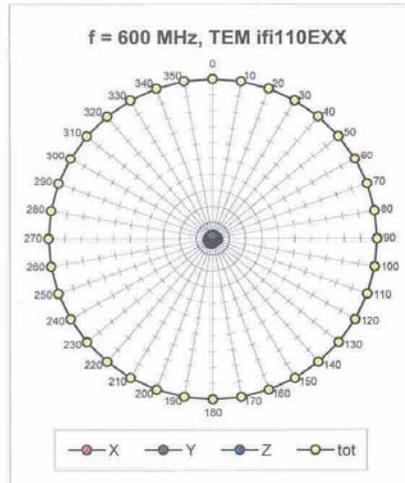


Uncertainty of Frequency Response of H-field: $\pm 6.3\%$ ($k=2$)

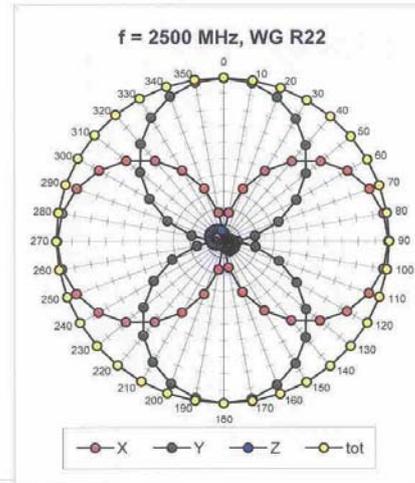
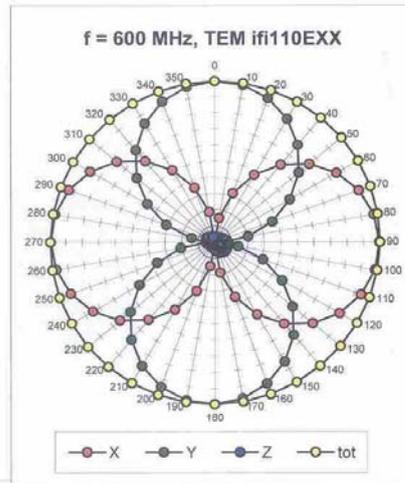
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Receiving Pattern (ϕ), $\vartheta = 90^\circ$



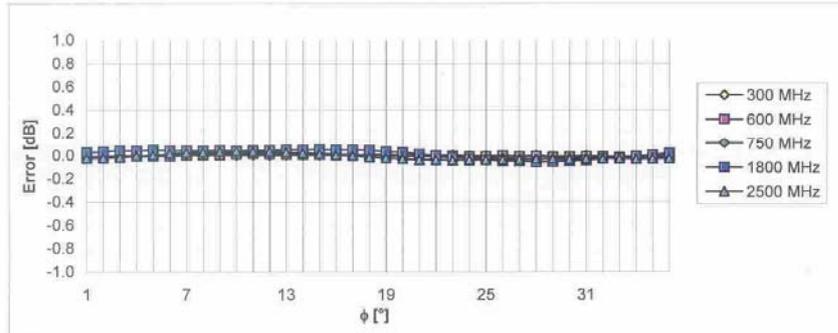
Receiving Pattern (ϕ), $\vartheta = 0^\circ$



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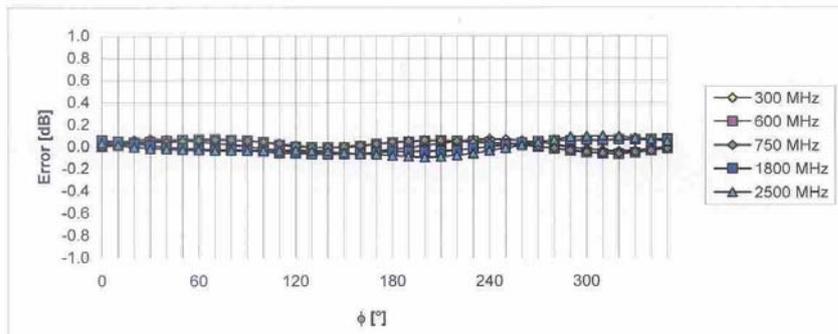
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Receiving Pattern (ϕ), $\vartheta = 90^\circ$



Uncertainty of Axial Isotropy Assessment: $\pm 0.5\%$ (k=2)

Receiving Pattern (ϕ), $\vartheta = 0^\circ$

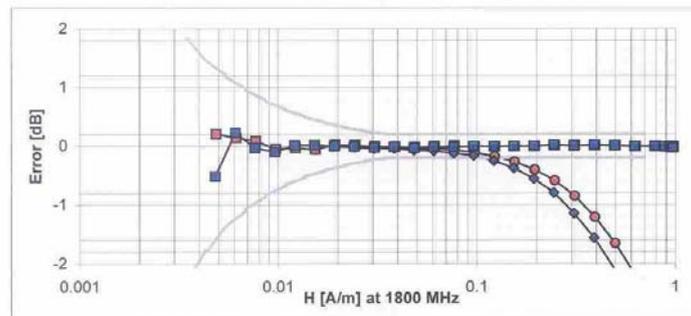
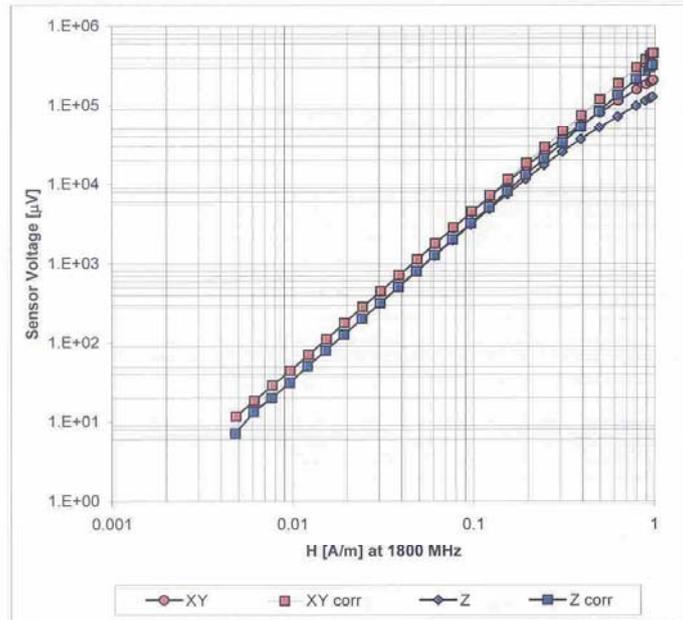


Uncertainty of Axial Isotropy Assessment: $\pm 0.5\%$ (k=2)

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Dynamic Range f(H-field) (Waveguide R22, f = 1800 MHz)

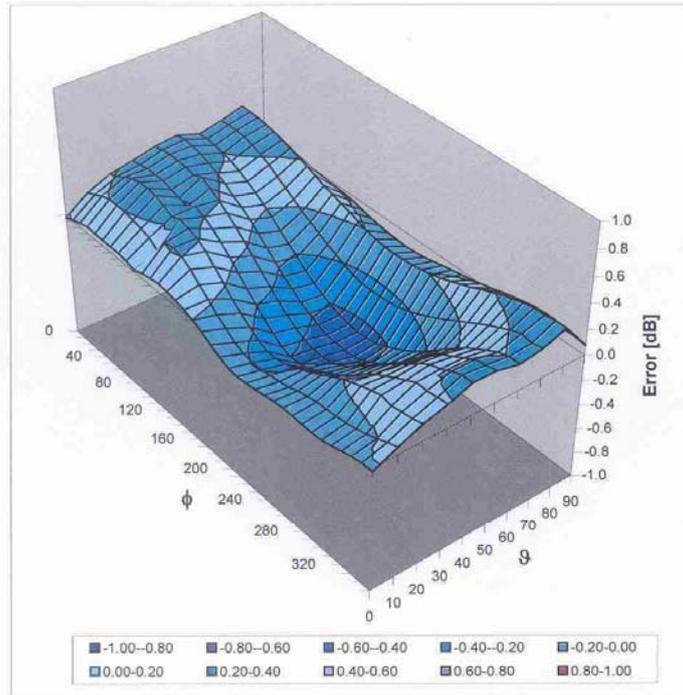


Uncertainty of Linearity Assessment: $\pm 0.6\%$ ($k=2$)

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Deviation from Isotropy in Air
Error (ϕ, ϑ), $f = 900$ MHz



Uncertainty of Spherical Isotropy Assessment: $\pm 2.6\%$ ($k=2$)

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Other Probe Parameters

Sensor Arrangement	Rectangular
Connector Angle (°)	-154.1
Mechanical Surface Detection Mode	enabled
Optical Surface Detection Mode	disabled
Probe Overall Length	337 mm
Probe Body Diameter	10 mm
Tip Length	20 mm
Tip Diameter	6.0 mm
Probe Tip to Sensor X Calibration Point	3 mm
Probe Tip to Sensor Y Calibration Point	3 mm
Probe Tip to Sensor Z Calibration Point	3 mm